OPAx383 Low-Power, High-Precision, 2.5MHz, Zero-Drift Op Amp

1 Features

- Ultra-low offset voltage: ±5µV (maximum)
- Zero drift: ±0.025µV/°C
- Low-input bias current: 62pA (maximum)
- Low noise: 32nV/√Hz at 1kHz
- No 1/f noise: 650nV$_{PP}$ (0.1Hz to 10Hz)
- Common-mode input range ±100mV beyond supply rails
- Gain bandwidth: 2.5MHz
- Quiescent current: 65µA per amplifier
- Single supply: 1.7V to 5.5V
- Dual supply: ±0.85V to ±2.75V
- EMI and RFI filtered inputs

2 Applications

- Electronic thermometer
- Weigh scale
- Temperature transmitter
- Ventilators
- Data acquisition (DAQ)
- Semiconductor test
- Lab and field instrumentation
- Merchant network and server PSU
- Analog input module
- Pressure transmitter

3 Description

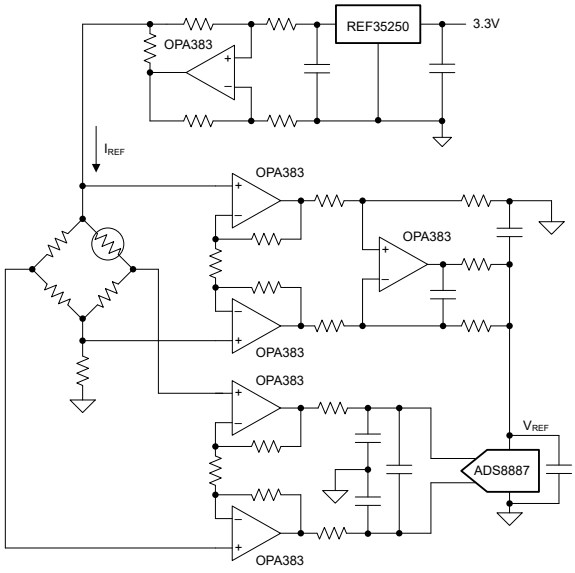
The OPA383, OPA2383, and OPA4383 (OPAx383) family of precision amplifiers offers state-of-the-art performance. With zero-drift technology, the OPAx383 offset voltage and offset drift provide unparalleled long-term stability. With a ultra-low 65µA of quiescent current, the OPAx383 are able to achieve 2.5MHz of bandwidth, a broadband noise of 32nV/√Hz, and a 1/f noise at 650nV$_{PP}$. These specifications are crucial to achieve extremely-high precision and no degradation of linearity in 16-bit to 24-bit analog to digital converters (ADCs). The OPAx383 feature flat bias current over temperature; therefore, little to no calibration is needed in high input impedance applications over temperature.

All versions are specified over the industrial temperature range of –40°C to +125°C.

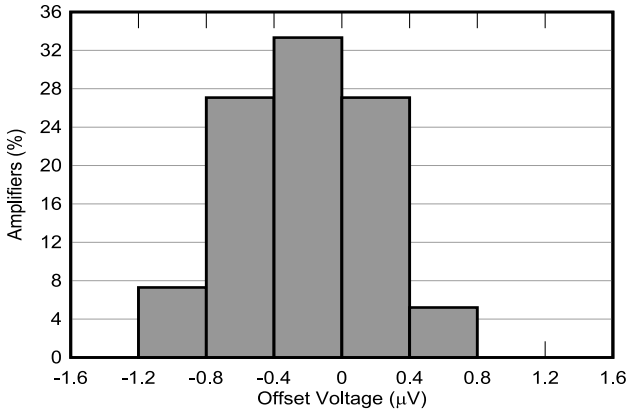
Device Information

PART NUMBER	CHANNEL COUNT	PACKAGE(1)	PACKAGE SIZE
OPA383	Single	DBV (SOT-23, 5)	2.9mm × 2.8mm
		DCK (SC70, 5)(2)	2.0mm × 2.1mm
OPA383, Shutdown	Single	YCH (DSBGA, 6)	1.01mm x 0.69mm
OPA2383	Dual	D (SOIC, 8)(2)	4.9mm × 6.0mm
		DGK (VSSOP, 8)	3.0mm × 4.9mm
OPA4383	Quad	PW (TSSOP, 14)	5.0mm × 6.4mm

(1) For more information, see Section 10.
(2) Preview information (not Production Data).



The OPA383 as a Bridge Sensor Front End



Ultra-Low Input Offset Voltage

An IMPORTANT NOTICE at the end of this data sheet addresses availability, warranty, changes, use in safety-critical applications, intellectual property matters and other important disclaimers. PRODUCTION DATA.

Table of Contents

1 Features....1
2 Applications....1
3 Description....1
4 Pin Configuration and Functions....3
5 Specifications....6
5.1 Absolute Maximum Ratings....6
5.2 ESD Ratings....6
5.3 Recommended Operating Conditions....6
5.4 Thermal Information OPA383....7
5.5 Thermal Information OPA2383....7
5.6 Thermal Information OPA4383....7
5.7 Electrical Characteristics....8
5.8 Typical Characteristics....11
6 Detailed Description....18
6.1 Overview....18
6.2 Functional Block Diagram....18
6.3 Feature Description....19
6.4 Device Functional Modes....19
7 Application and Implementation....20
7.1 Application Information....20
7.2 Typical Applications....20
7.3 Power Supply Recommendations....23
7.4 Layout....23
8 Device and Documentation Support....24
8.1 Device Support....24
8.2 Receiving Notification of Documentation Updates....24
8.3 Support Resources....24
8.4 Trademarks....24
8.5 Electrostatic Discharge Caution....24
8.6 Glossary....24
9 Revision History....25
10 Mechanical, Packaging, and Orderable Information....25

Copyright © 2026 Texas Instruments Incorporated

4 Pin Configuration and Functions

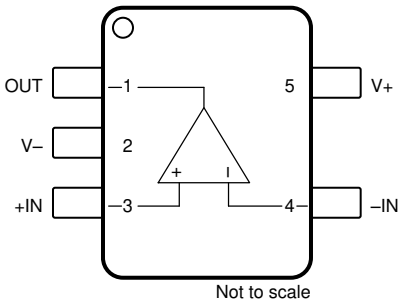


Figure 4-1. OPA383: DBV (Preview) Package, 5-Pin SOT-23 (Top View)

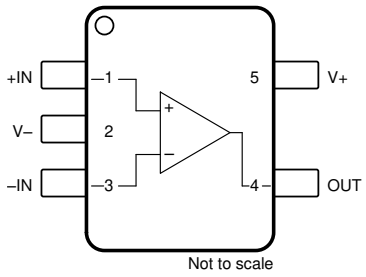


Figure 4-2. OPA383: DCK (Preview) Package, 5-Pin SC70 (Top View)

Table 4-1. Pin Functions: OPA383

PIN			TYPE	DESCRIPTION
NAME	NO.			
	DBV (SOT-23)	DCK (SC70)		
–IN	4	3	Input	Inverting input
+IN	3	1	Input	Noninverting input
OUT	1	4	Output	Output
V–	2	2	Power	Negative (lowest) power supply
V+	5	5	Power	Positive (highest) power supply

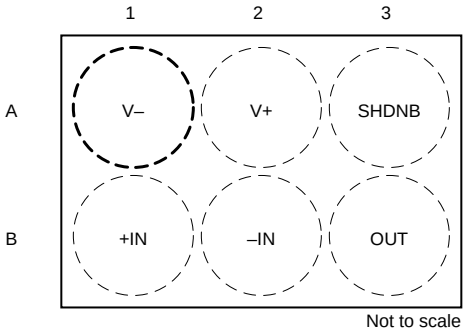


Figure 4-3. OPA383: YCH Package, 6-Pin DSBGA (Top View)

Table 4-2. Pin Functions: OPA383 DSBGA

PIN		TYPE	DESCRIPTION
NAME	NO.		
	YBJ (DSBGA)		
+IN	B1	Input	Inverting input
–IN	B2	Input	Noninverting input
OUT	B3	Output	Output
V–	A1	Power	Negative (lowest) power supply
V+	A2	Power	Positive (highest) power supply
$\overline{\text{SHDN}}$ / SHDNB	A3	Input	Shutdown logic: Low = amp disabled, High = amp enabled

Copyright © 2026 Texas Instruments Incorporated

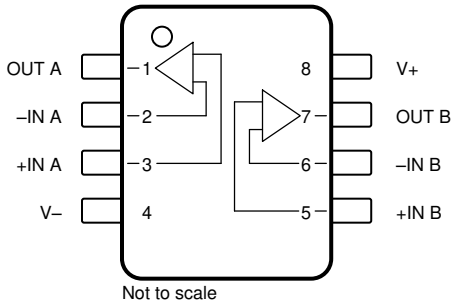


Figure 4-4. OPA2383: DDF (Preview) Package, 8-Pin SOT-23, and DGK Package, 8-Pin VSSOP (Top View)

Table 4-3. Pin Functions: OPA2383

PIN			TYPE	DESCRIPTION
NAME	NO.			
	DDF (SOT-23)	DGK (VSSOP)		
–IN A	2	2	Input	Inverting input, channel A
–IN B	6	6	Input	Inverting input, channel B
+IN A	3	3	Input	Noninverting input, channel A
+IN B	5	5	Input	Noninverting input, channel B
OUT A	1	1	Output	Output, channel A
OUT B	7	7	Output	Output, channel B
V–	4	4	Power	Negative (lowest) power supply
V+	8	8	Power	Positive (highest) power supply

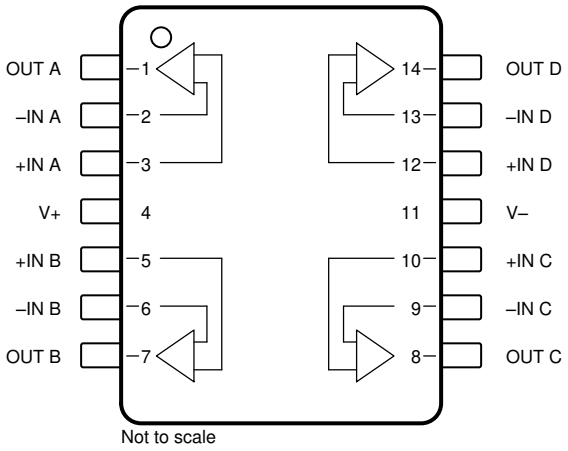


Figure 4-5. OPA4383: PW (Preview) Package, 14-Pin TSSOP (Top View)

Table 4-4. Pin Functions: OPA4383

PIN		TYPE	DESCRIPTION
NAME	NO.		
–IN A	2	Input	Inverting input, channel A
–IN B	6	Input	Inverting input, channel B
–IN C	9	Input	Inverting input, channel C
–IN D	13	Input	Inverting input, channel D
+IN A	3	Input	Noninverting input, channel A
+IN B	5	Input	Noninverting input, channel B
+IN C	10	Input	Noninverting input, channel C

Copyright © 2026 Texas Instruments Incorporated

Table 4-4. Pin Functions: OPA4383 (continued)

PIN		TYPE	DESCRIPTION
NAME	NO.		
+IN D	12	Input	Noninverting input, channel D
OUT A	1	Output	Output, channel A
OUT B	7	Output	Output, channel B
OUT C	8	Output	Output, channel C
OUT D	14	Output	Output, channel D
V–	11	Power	Negative (lowest) power supply
V+	4	Power	Positive (highest) power supply

Copyright © 2026 Texas Instruments Incorporated

5 Specifications

5.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)(1)

			MIN	MAX	UNIT
V_S	Supply voltage, V_S = (V+) – (V–)	Single-supply		6	V
		Dual-supply		±3	
	Input voltage, all pins (OPA383YCHR) (2) (3)	Common-mode	(V–) – 0.5	(V–) + 6	V
	Input voltage, all pins	Common-mode	(V–) – 0.5	(V+) + 0.5	V
		Differential		(V+) – (V–) + 0.2	
	Input current, all pins			±10	mA
	Output short circuit(4)		Continuous	Continuous	
T_A	Operating temperature		–55	150	°C
T_J	Junction temperature		–55	150	°C
T_{stg}	Storage temperature		–65	150	°C

(1) Operation outside the *Absolute Maximum Ratings* may cause permanent device damage. *Absolute Maximum Ratings* do not imply functional operation of the device at these or any other conditions beyond those listed under *Recommended Operating Conditions*. If used outside the *Recommended Operating Conditions* but within the *Absolute Maximum Ratings*, the device may not be fully functional, and this may affect device reliability, functionality, performance, and shorten the device lifetime.
(2) Input pins can swing beyond (V+) as long as they stay with in 6.0V. No diode structure from input pins to (V+).
(3) Input pins are diode-clamped to (V–). Input signals that 0.3V below (V–) must be current-limited to 10mA or less.
(4) Short-circuit to ground, one amplifier per package.

5.2 ESD Ratings

			VALUE	UNIT
OPA383 PACKAGES				
$V_{(ESD)}$	Electrostatic discharge	Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001(1)	±2000	V
		Charged-device model (CDM), per ANSI/ESDA/JEDEC JS-002(2)	±1000	V
ALL OTHER PACKAGES				
$V_{(ESD)}$	Electrostatic discharge	Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001(1)	±3000	V
		Charged-device model (CDM), per ANSI/ESDA/JEDEC JS-002(2)	±1000	

(1) JEDEC document JEP155 states that 500V HBM allows safe manufacturing with a standard ESD control process.
(2) JEDEC document JEP157 states that 250V CDM allows safe manufacturing with a standard ESD control process.

5.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

			MIN	NOM	MAX	UNIT
V_S	Supply voltage, V_S = (V+) – (V–)	Single-supply	1.7		5.5	V
		Dual-supply	±0.85		±2.75	
T_A	Specified temperature		–40		125	°C

Copyright © 2026 Texas Instruments Incorporated

5.4 Thermal Information OPA383

THERMAL METRIC(1)		OPA383		UNIT
		DBV (SOT-23)	YCH (DSBGA)	
		5 PINS	6 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance	183.4	136.5	°C/W
$R_{\theta JC(top)}$	Junction-to-case(top) thermal resistance	110.7	1.15	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	49.2	39.5	°C/W
ψ_{JT}	Junction-to-top characterization parameter	29.5	0.4	°C/W
ψ_{JB}	Junction-to-board characterization parameter	49.1	39.5	°C/W
$R_{\theta JC(bot)}$	Junction-to-case(bottom) thermal resistance	N/A	N/A	°C/W

(1) For more information about traditional and new thermal metrics, see the *Semiconductor and IC Package Thermal Metrics* application report.

5.5 Thermal Information OPA2383

THERMAL METRIC(1)		OPA2383	UNIT
		DGK (VSSOP)	
		8 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance	165	°C/W
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	53	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	87	°C/W
Ψ_{JT}	Junction-to-top characterization parameter	4.9	°C/W
Ψ_{JB}	Junction-to-board characterization parameter	85	°C/W
$R_{\theta JC(bot)}$	Junction-to-case (bottom) thermal resistance	N/A	°C/W

(1) For more information about traditional and new thermal metrics, see the *Semiconductor and IC Package Thermal Metrics* application report.

5.6 Thermal Information OPA4383

THERMAL METRIC(1)		OPA4383	UNIT
		PW (TSSOP)	
		14 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance	113.9	°C/W
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	42.9	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	69.1	°C/W
Ψ_{JT}	Junction-to-top characterization parameter	2.2	°C/W
Ψ_{JB}	Junction-to-board characterization parameter	68.4	°C/W
$R_{\theta JC(bot)}$	Junction-to-case (bottom) thermal resistance	N/A	°C/W

(1) For more information about traditional and new thermal metrics, see the *Semiconductor and IC Package Thermal Metrics* application report.

Copyright © 2026 Texas Instruments Incorporated

5.7 Electrical Characteristics

at T_A = 25°C, R_L = 10kΩ connected to V_S / 2, V_S = 1.7V to 5.5V, V_{CM} = V_S / 2, V_{OUT} = V_S / 2, and min and max specification established from manufacturing final test (unless otherwise noted)

PARAMETER		TEST CONDITIONS		MIN	TYP	MAX	UNIT
OFFSET VOLTAGE							
V_{OS}	Input offset voltage(1)	V_S = 5.5V			±0.4	±5	µV
		T_A = –40°C to +125°C			±0.5		
dV_{OS}/dT	Input offset voltage drift	T_A = –40°C to +125°C(1)			±0.004	±0.025	µV/°C
PSRR	Power supply rejection ratio				±0.05	±0.9	µV/V
		T_A = –40°C to +125°C(1)				±0.9	
INPUT BIAS CURRENT							
I_B	Input bias current(1)				±10	±62	pA
		T_A = –40°C to +85°C				±76	
		T_A = –40°C to +125°C				±212	
I_B	Input bias current(1)	OPA383YCHR			±85	±140	pA
		OPA383YCHR, T_A = –40°C to +85°C				±3.3	nA
		OPA383YCHR, T_A = –40°C to +125°C				±20.5	
I_{OS}	Input offset current(1)				±20	±123	pA
		T_A = –40°C to +125°C				±300	
I_{OS}	Input offset current(1)	OPA383YCHR			±20	±150	pA
		OPA383YCHR, T_A = –40°C to +125°C				±750	
NOISE							
	Input voltage noise	f = 0.1Hz to 10Hz			650		nV_{PP}
					100		nV_{RMS}
e_N	Input voltage noise density	f = 1Hz			32		nV/√Hz
		f = 10Hz			32		
		f = 100Hz			32		
		f = 1kHz			32		
i_N	Input current noise	f = 1kHz			100		fA/√Hz
V_{CM}	Common-mode voltage range	V_S = 5.5V		(V–) – 0.1		(V+) + 0.1	V
		V_S = 1.7V		(V–) – 0.1		(V+)	
INPUT VOLTAGE							
CMRR	Common-mode rejection ratio	(V–) – 0.1V < V_{CM} < (V+) + 0.1V, V_S = 5.5V		122	135		dB
			T_A = –40°C to +125°C(1)	120			
		(V–) – 0.1V < V_{CM} < (V+), V_S = 1.7V(1)		116	130		
			T_A = –40°C to +125°C	114			
INPUT CAPACITANCE							
Z_{ID}	Differential				100 || 6		MΩ || pF
Z_{ICM}	Common-mode				60 || 1.5		GΩ || pF
OPEN-LOOP GAIN							
A_{OL}	Open-loop voltage gain	(V–) + 100mV < V_{OUT} < (V+) – 100mV	V_S = 5.5V	120	145		dB
			V_S = 1.7V(1)	120			
			T_A = –40°C to +125°C(1)	119			
		(V–) + 150mV < V_{OUT} < (V+) – 150mV, R_L = 2kΩ	V_S = 5.5V	119	140		
			V_S = 1.7V(1)	119			
			T_A = –40°C to +125°C(1)	118			

Copyright © 2026 Texas Instruments Incorporated

5.7 Electrical Characteristics (continued)

at T_A = 25°C, R_L = 10kΩ connected to V_S / 2, V_S = 1.7V to 5.5V, V_{CM} = V_S / 2, V_{OUT} = V_S / 2, and min and max specification established from manufacturing final test (unless otherwise noted)

PARAMETER		TEST CONDITIONS		MIN	TYP	MAX	UNIT
FREQUENCY RESPONSE							
GBW	Gain-bandwidth product				2.5		MHz
SR	Slew rate	4V step, G = +1			1		V/µs
t_S	Settling time	To 0.1%, 1V step, G = +1			5.4		µs
		To 0.01%, 1V step, G = +1			48		
	Overload recovery time	V_{IN} × G > V_S			2200		ns
	Chopping clock frequency(1)				130		kHz
THD+N	Total harmonic distortion + noise	V_{OUT} = 1V_{RMS}, G = +1, f = 1kHz			0.0012 %		
OUTPUT							
	Voltage output swing from rail	No load			1	10	mV
					5	30	
		R_L = 2kΩ			60	150	
		T_A = –40°C to +125°C(1)				155	
	Voltage output swing from rail	OPA383YCHR, No load (Positive rail headroom)			1	25	mV
		OPA383YCHR, No load (Negative rail headroom)			1	10	
		OPA383YCHR			20	30	
		OPA383YCHR, R_L = 2kΩ			100	150	
		OPA383YCHR, T_A = –40°C to +125°C(1)				155	
	High linearity output swing range(1)	A_{OL} > 119dB		(V–) + 0.075		(V+) – 0.075	V
			R_L = 2kΩ	(V–) + 0.150		(V+) – 0.150	
I_{SC}	Short-circuit current	V_S = 5.5V			±28		mA
		V_S = 1.7V			±2.5		
C_{LOAD}	Capacitive load drive			See the typical characteristic curve			
R_O	Open-loop output impedance	f = 1MHz			2.5		kΩ
POWER SUPPLY							
I_Q	Quiescent current per amplifier	I_O = 0mA			65	100	µA
			T_A = –40°C to 125°C(1)			110	
	Turn-on time	At V_S = 5.5V, V_S ramp rate > 0.05V/µs, settle to 1%			180		µs
SHUTDOWN							
I_{QSD}	Quiescent current per amplifier(1)	V_S = 5V, $\overline{SHDN}$ = V– (Amplifiers disabled)			90	130	nA
			T_A = –40°C to 85°C			200	
			T_A = –40°C to 125°C			455	
		V_S = 3.3V, $\overline{SHDN}$ = V– (Amplifiers disabled)			80	120	
			T_A = –40°C to 85°C			180	
			T_A = –40°C to 125°C			395	
Z_{SHDN}	Output impedance during shutdown	Amplifier disabled, $\overline{SHDN}$ = V–			12 || 7		GΩ || pF
V_{IH}	Logic high threshold voltage (amplifier enabled)			(V–) + 0.85V			V
V_{IL}	Logic low threshold voltage (amplifier disabled)					(V–) + 0.35V	V
t_{ON}	Amplifier enable(2)	V_S = 3.3V, G = +1, V_{CM} = V_S / 2, V_O = 0.9 × V_S / 2, R_L connected to V–			158		µs
t_{OFF}	Amplifier disable time(2)	V_S = 3.3V, G = +1, V_{CM} = V_S / 2, V_O = 0.1 × V_S / 2, R_L connected to V–			18		µs

Copyright © 2026 Texas Instruments Incorporated

5.7 Electrical Characteristics (continued)

at T_A = 25°C, R_L = 10kΩ connected to V_S / 2, V_S = 1.7V to 5.5V, V_{CM} = V_S / 2, V_{OUT} = V_S / 2, and min and max specification established from manufacturing final test (unless otherwise noted)

PARAMETER		TEST CONDITIONS		MIN	TYP	MAX	UNIT
I_{BSD}	$\overline{SHDN}$ pin input bias current(1)	V_S = 5V, $\overline{SHDN}$ = V– (Amplifiers disabled)			31	200	pA
			T_A = –40°C to 85°C			210	
			T_A = –40°C to 125°C			610	
		V_S = 3.3V, $\overline{SHDN}$ = V– (Amplifiers disabled)			13	210	
			T_A = –40°C to 85°C			220	
			T_A = –40°C to 125°C			580	
		V_S = 5V, $\overline{SHDN}$ = V+ (Amplifiers enabled)			105	200	pA
			T_A = –40°C to 85°C			2.35	nA
			T_A = –40°C to 125°C			16.5	
		V_S = 3.3V, $\overline{SHDN}$ = V+ (Amplifiers enabled)			63	130	pA
			T_A = –40°C to 85°C			3.1	nA
			T_A = –40°C to 125°C			21.2	

(1) Specification established from device population bench system measurements across multiple lots.
(2) Disable time (t_{OFF}) and enable time (t_{ON}) are defined as the time interval between the 50% point of the signal applied to the $\overline{SHDN}$ pin and the point at which the output voltage reaches the 10% (disable) or 90% (enable) level.

Copyright © 2026 Texas Instruments Incorporated

5.8 Typical Characteristics

at T_A = 25°C, V_S = ±2.75V, V_{CM} = V_S / 2, R_{LOAD} = 10kΩ connected to V_S / 2, and C_L = 50pF (unless otherwise noted)

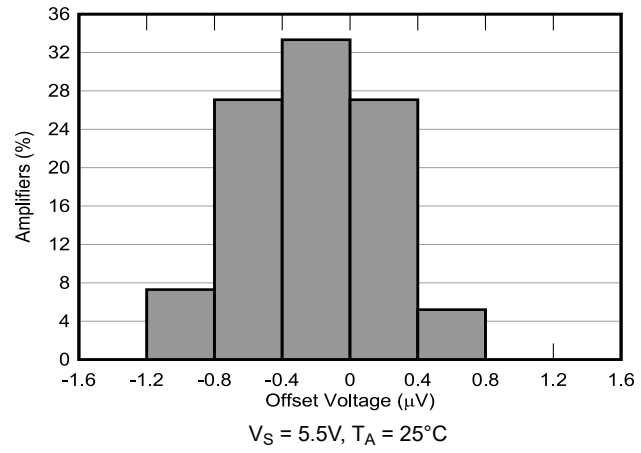


Figure 5-1. Offset Voltage Distribution

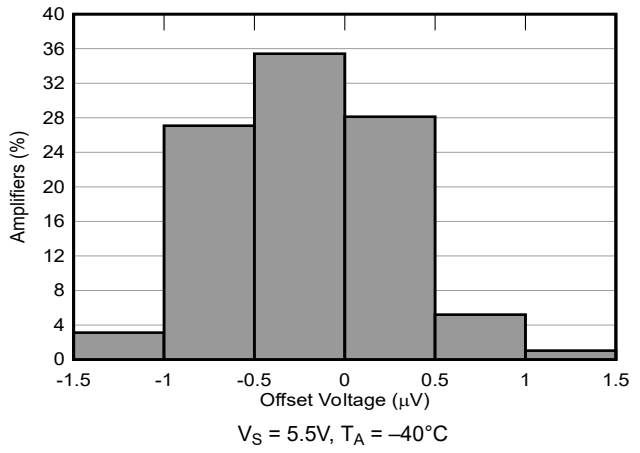


Figure 5-2. Offset Voltage Distribution

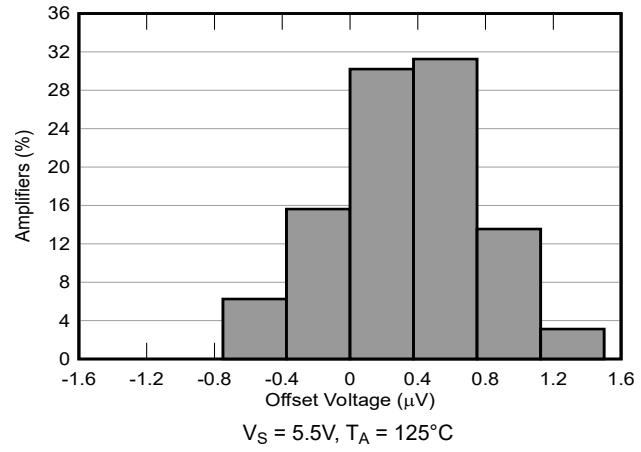


Figure 5-3. Offset Voltage Distribution

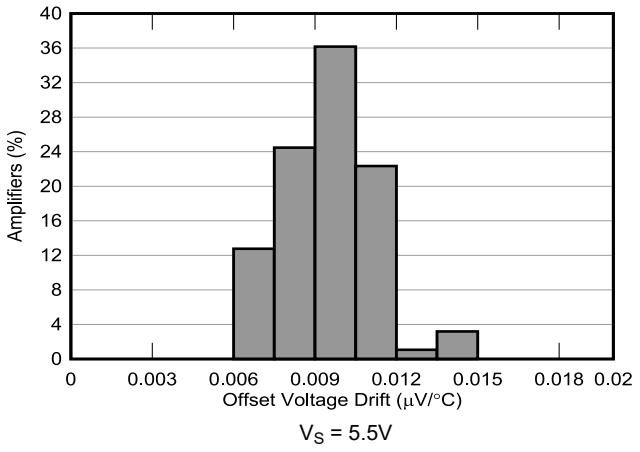


Figure 5-4. Offset Voltage Drift Distribution

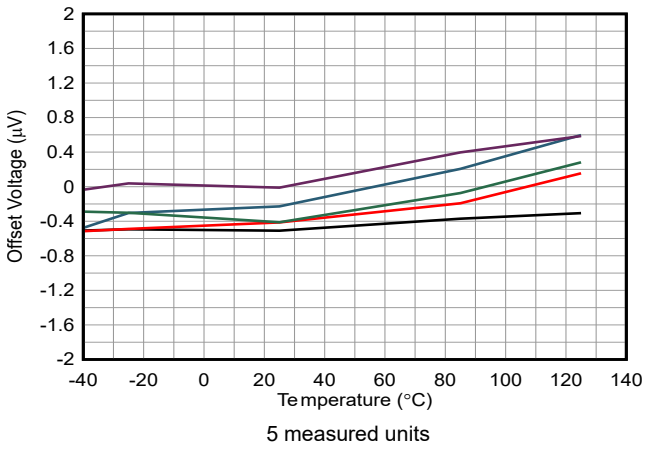


Figure 5-5. Offset Voltage vs Temperature

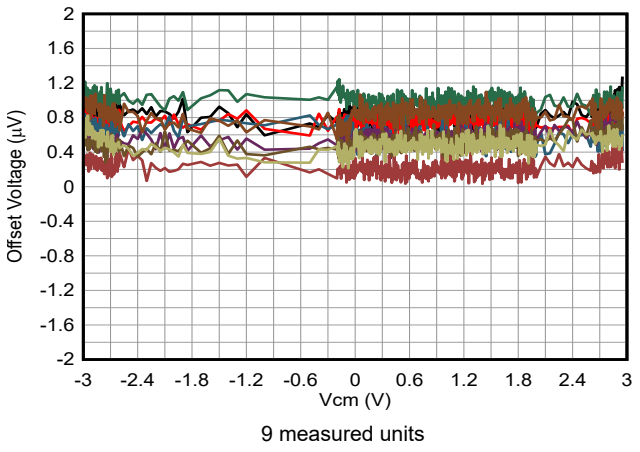


Figure 5-6. Offset Voltage vs Common-Mode Voltage

Copyright © 2026 Texas Instruments Incorporated

5.8 Typical Characteristics (continued)

at T_A = 25°C, V_S = ±2.75V, V_{CM} = V_S / 2, R_{LOAD} = 10kΩ connected to V_S / 2, and C_L = 50pF (unless otherwise noted)

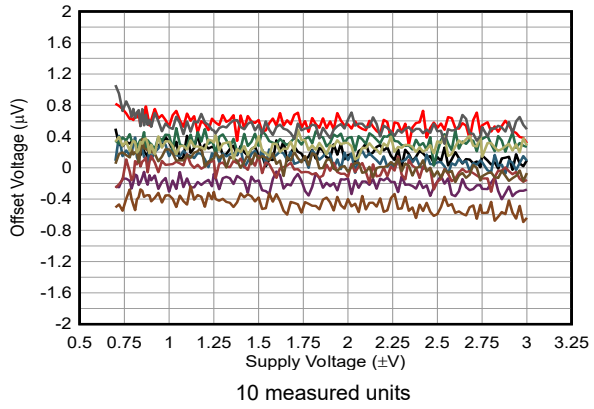


Figure 5-7. Offset Voltage vs Supply Voltage

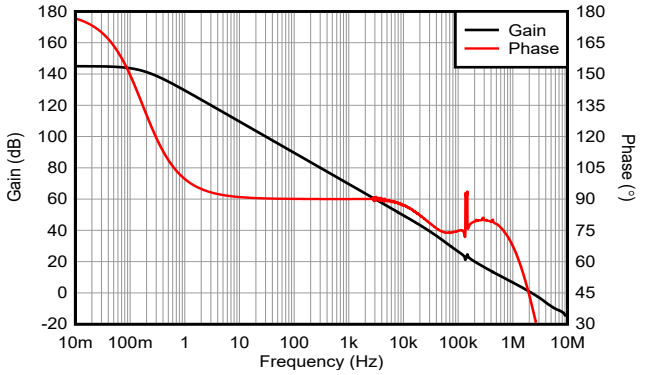


Figure 5-8. Open-Loop Gain and Phase vs Frequency

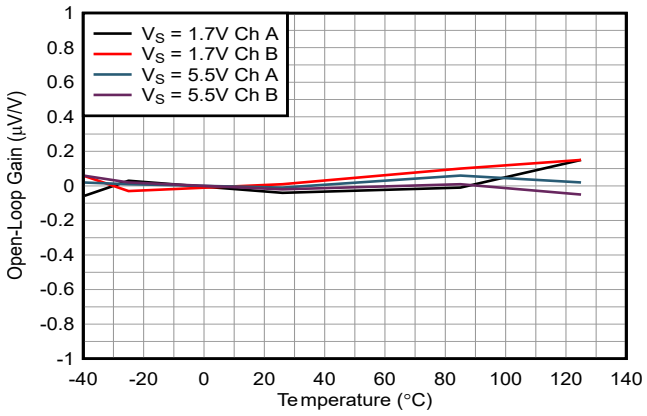


Figure 5-9. Open-Loop Gain vs Temperature

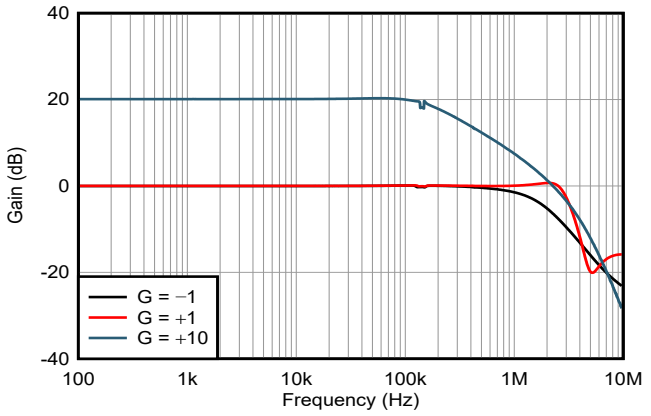


Figure 5-10. Closed-Loop Gain vs Frequency

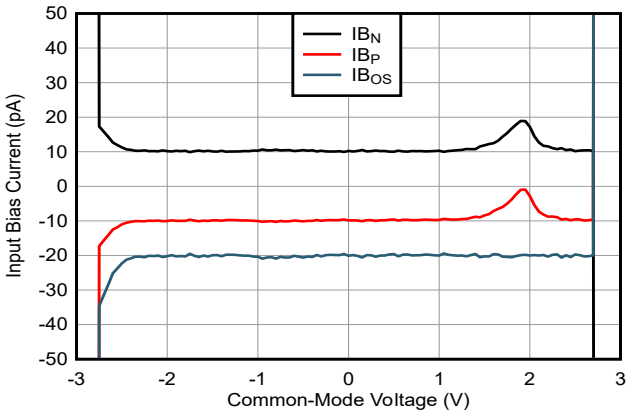


Figure 5-11. Input Bias Current vs Common-Mode Voltage

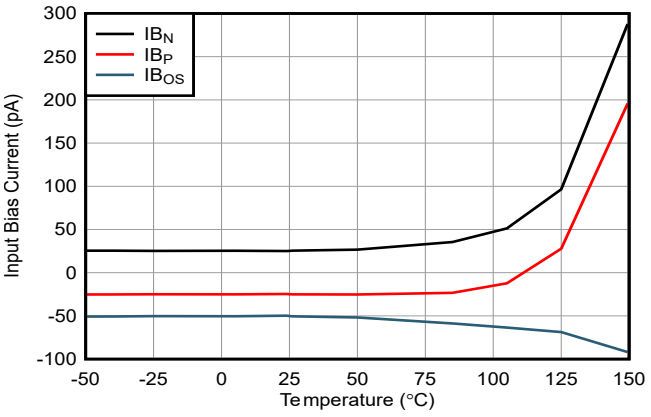


Figure 5-12. Input Bias Current vs Temperature

Copyright © 2026 Texas Instruments Incorporated

5.8 Typical Characteristics (continued)

at T_A = 25°C, V_S = ±2.75V, V_{CM} = V_S / 2, R_{LOAD} = 10kΩ connected to V_S / 2, and C_L = 50pF (unless otherwise noted)

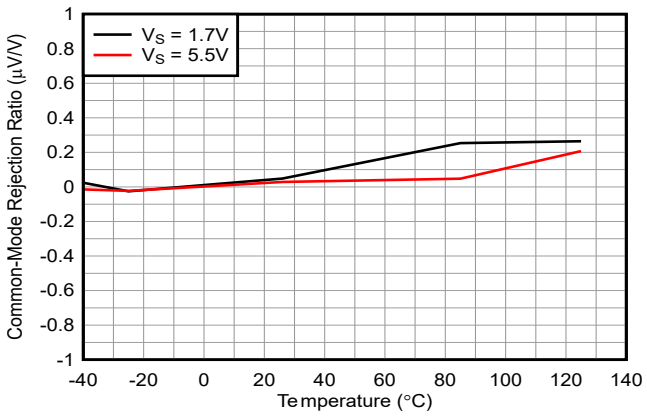


Figure 5-13. CMRR vs Temperature

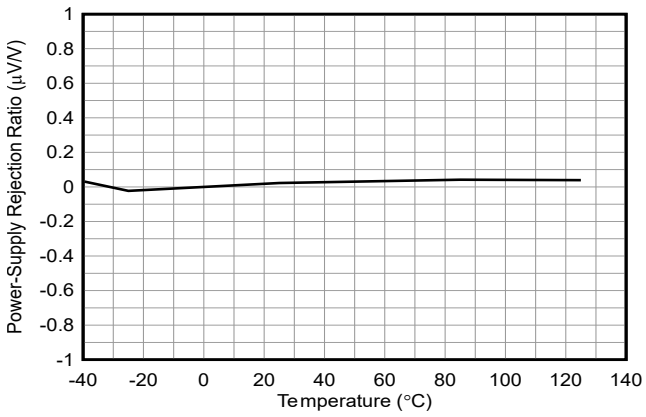


Figure 5-14. PSRR vs Temperature

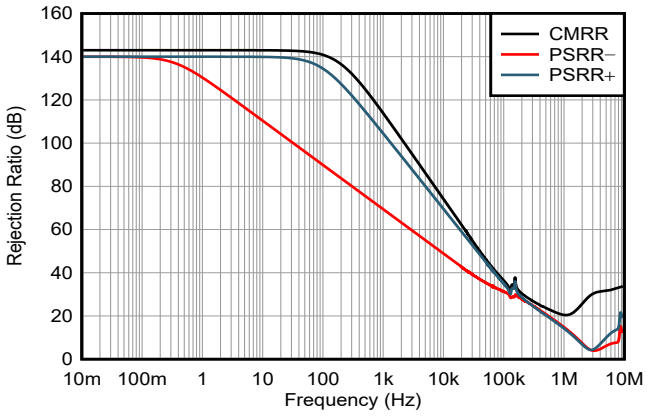


Figure 5-15. PSRR and CMRR vs Frequency

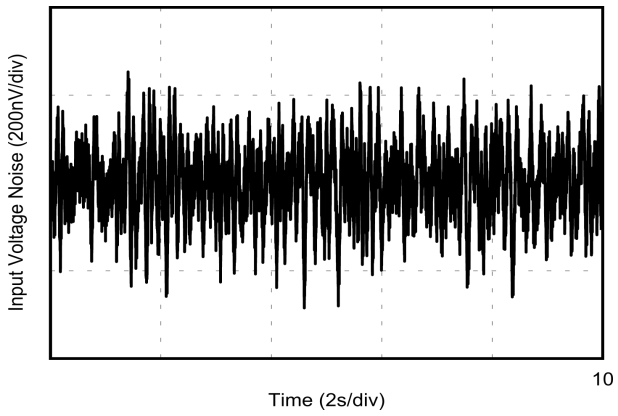


Figure 5-16. 0.1Hz to 10Hz Noise

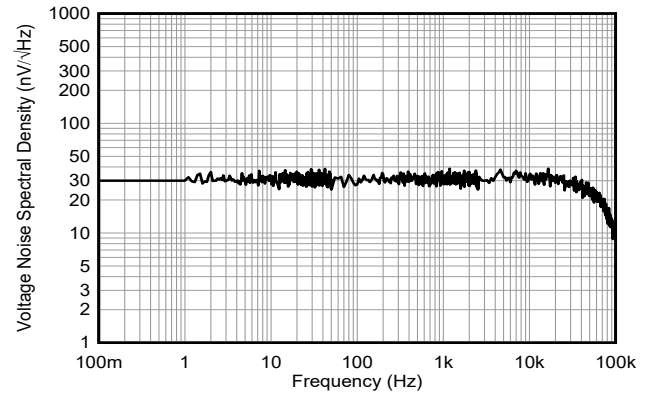


Figure 5-17. Input Voltage Noise Spectral Density vs Frequency

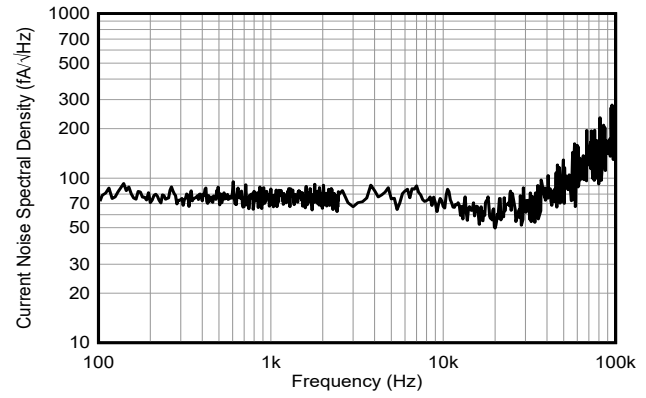


Figure 5-18. Input Current Noise Spectral Density vs Frequency

Copyright © 2026 Texas Instruments Incorporated

5.8 Typical Characteristics (continued)

at T_A = 25°C, V_S = ±2.75V, V_{CM} = V_S / 2, R_{LOAD} = 10kΩ connected to V_S / 2, and C_L = 50pF (unless otherwise noted)

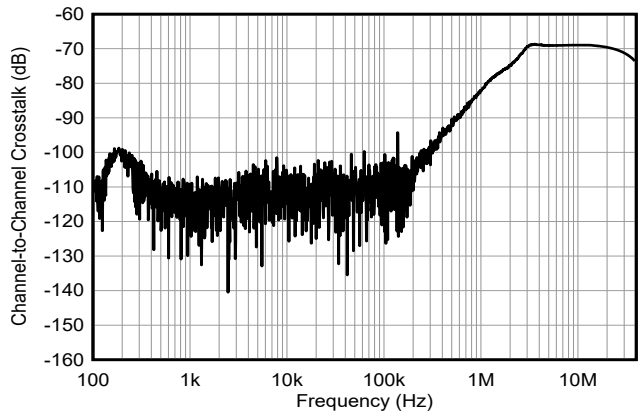


Figure 5-19. Channel-to-Channel Crosstalk

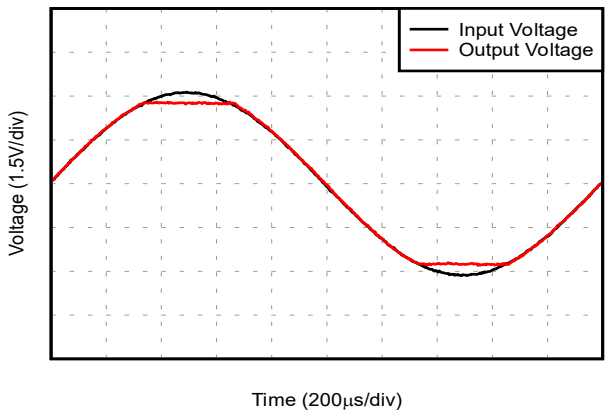
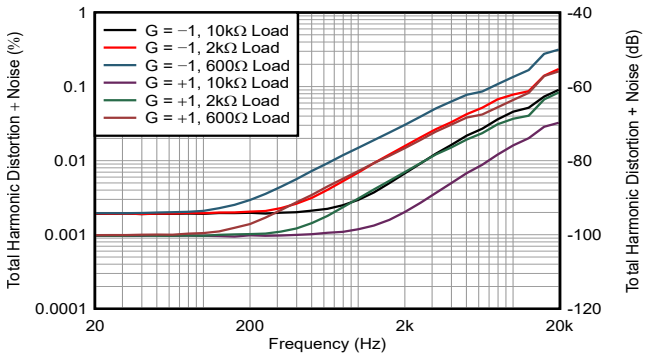
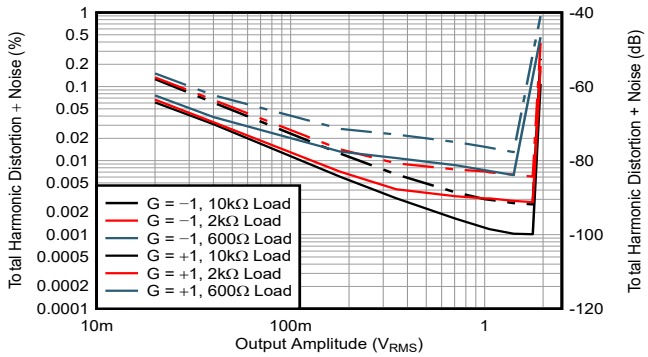


Figure 5-20. No Phase Reversal



V_S = 5.5V, V_{OUT} = 3V_{RMS}, BW = 80kHz

Figure 5-21. THD+N Ratio vs Frequency



V_S = 5.5V, f = 1kHz, BW = 80kHz

Figure 5-22. THD+N vs Output Amplitude

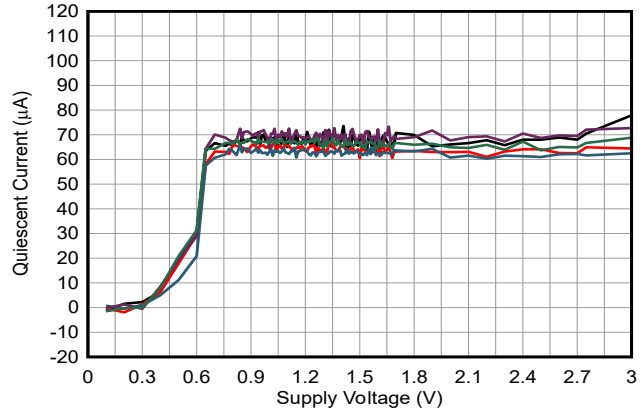


Figure 5-23. Quiescent Current vs Supply Voltage

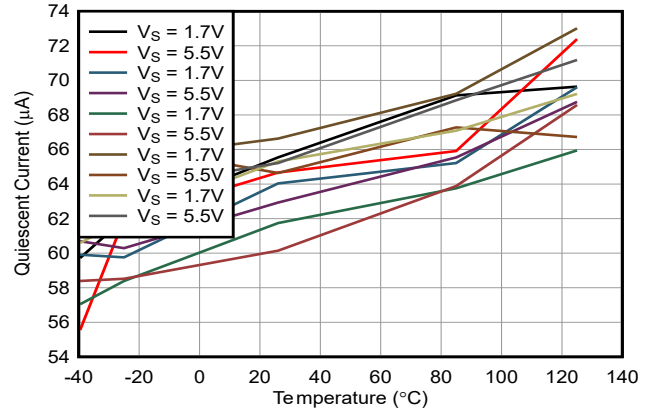


Figure 5-24. Quiescent Current vs Temperature

Copyright © 2026 Texas Instruments Incorporated

5.8 Typical Characteristics (continued)

at T_A = 25°C, V_S = ±2.75V, V_{CM} = V_S / 2, R_{LOAD} = 10kΩ connected to V_S / 2, and C_L = 50pF (unless otherwise noted)

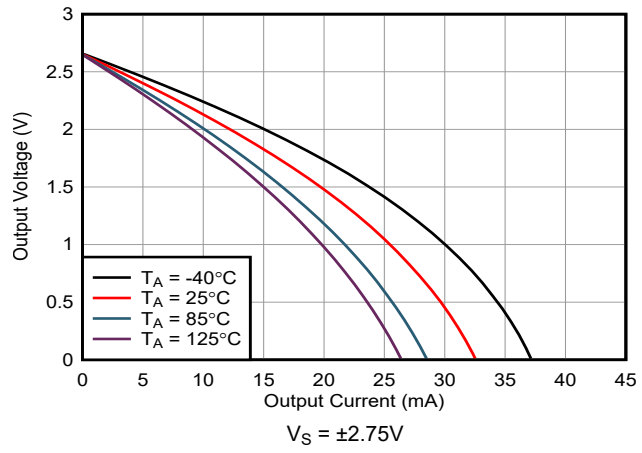


Figure 5-25. Output Voltage vs Output Current (Sourcing)

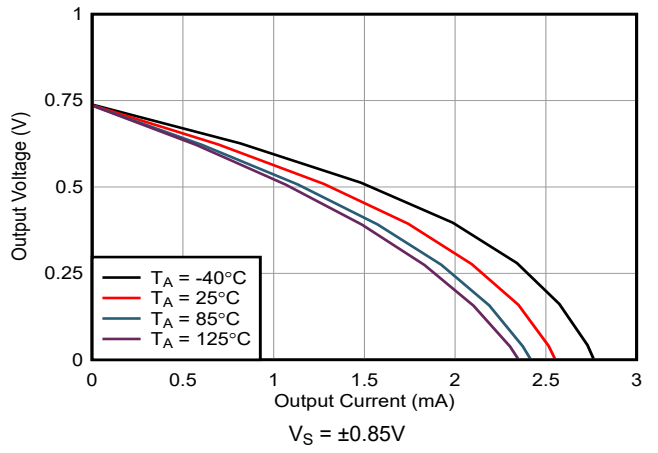


Figure 5-26. Output Voltage vs Output Current (Sourcing)

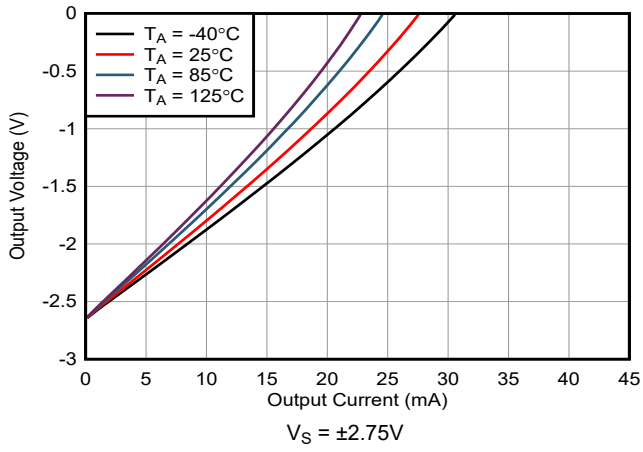


Figure 5-27. Output Voltage vs Output Current (Sinking)

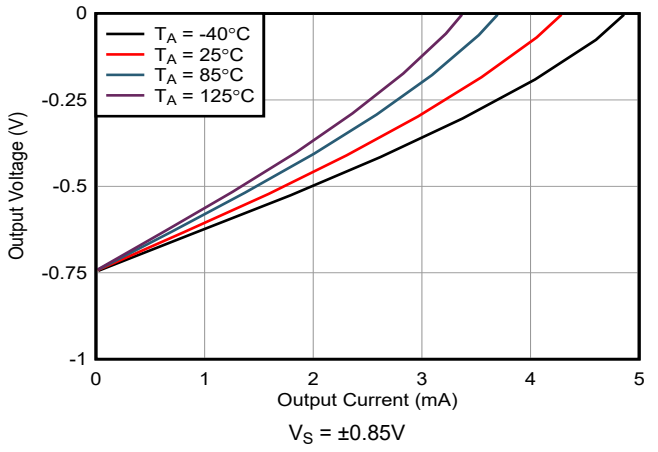


Figure 5-28. Output Voltage vs Output Current (Sinking)

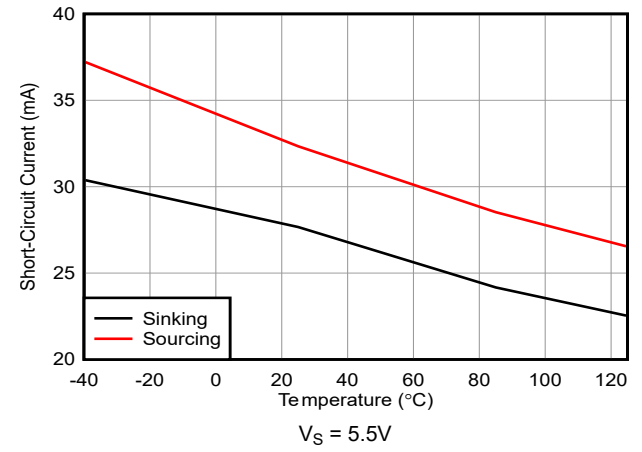


Figure 5-29. Short Circuit Current vs Temperature

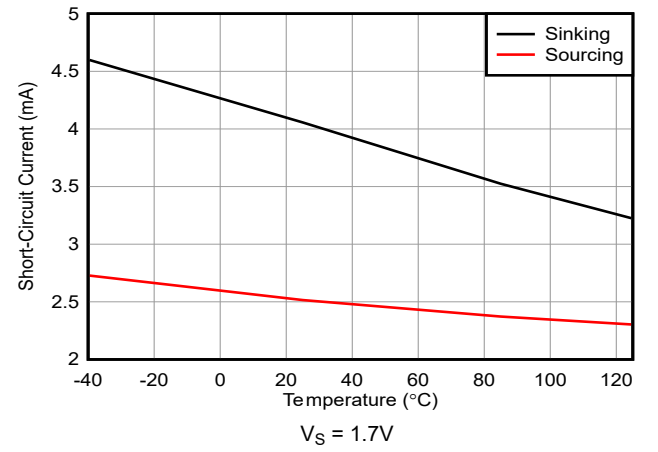


Figure 5-30. Short Circuit Current vs Temperature

Copyright © 2026 Texas Instruments Incorporated

5.8 Typical Characteristics (continued)

at T_A = 25°C, V_S = ±2.75V, V_{CM} = V_S / 2, R_{LOAD} = 10kΩ connected to V_S / 2, and C_L = 50pF (unless otherwise noted)

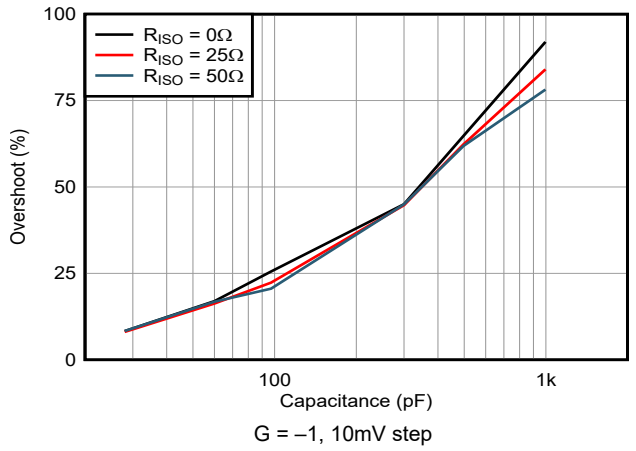


Figure 5-31. Small-Signal Overshoot vs Capacitive Load

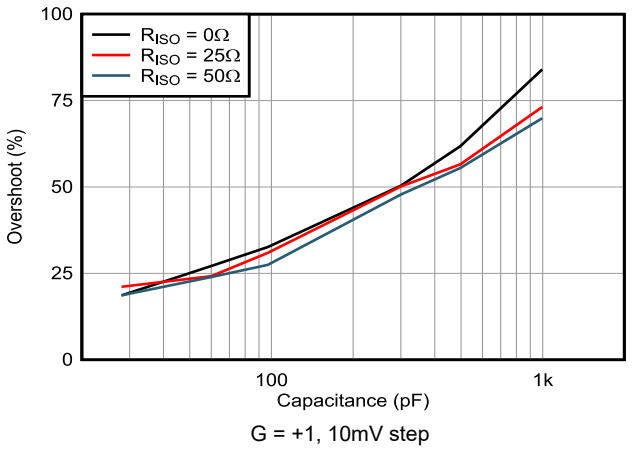


Figure 5-32. Small-Signal Overshoot vs Capacitive Load

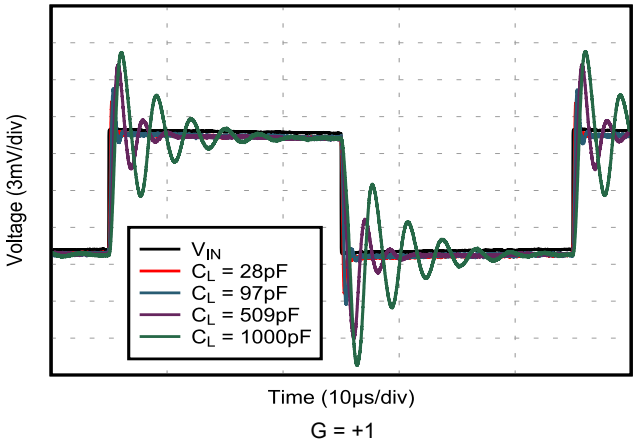


Figure 5-33. Small-Signal Voltage Transient Response vs Capacitive Load (C_L)

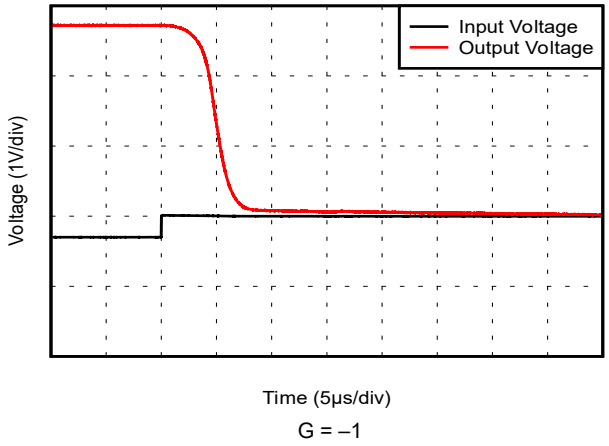


Figure 5-34. Overload Recovery

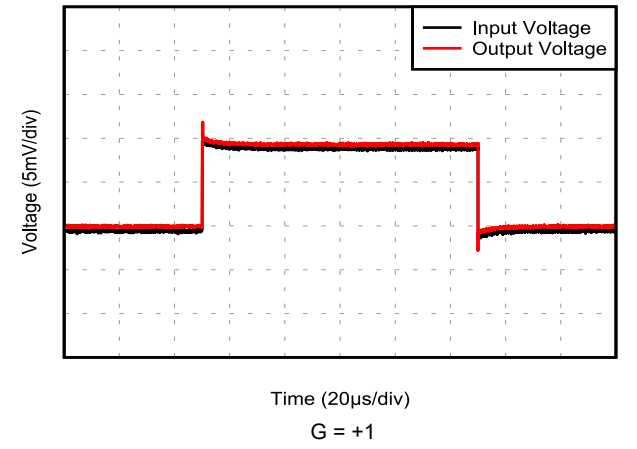


Figure 5-35. Small-Signal Step Response

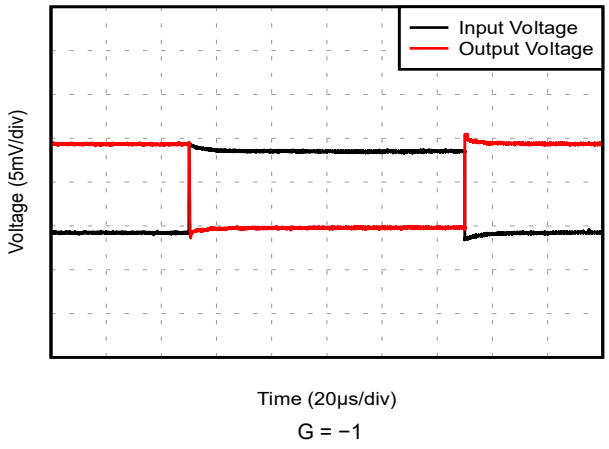


Figure 5-36. Small-Signal Step Response

Copyright © 2026 Texas Instruments Incorporated

5.8 Typical Characteristics (continued)

at T_A = 25°C, V_S = ±2.75V, V_{CM} = V_S / 2, R_{LOAD} = 10kΩ connected to V_S / 2, and C_L = 50pF (unless otherwise noted)

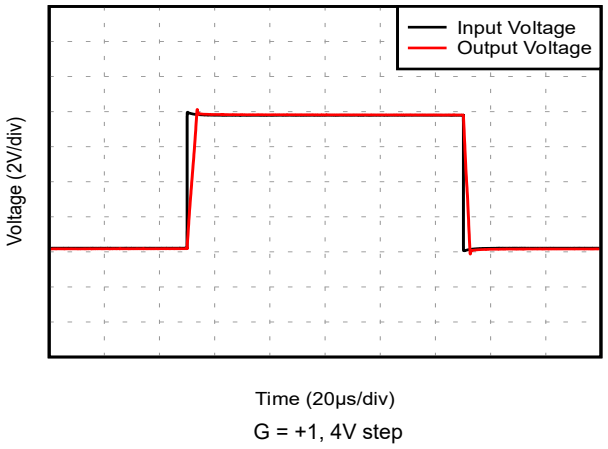


Figure 5-37. Large-Signal Step Response

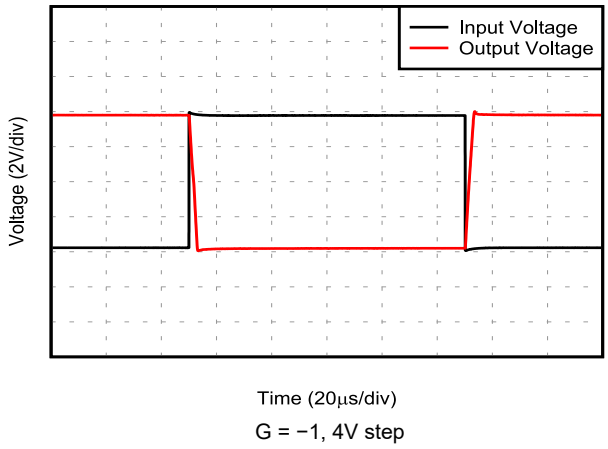


Figure 5-38. Large-Signal Step Response

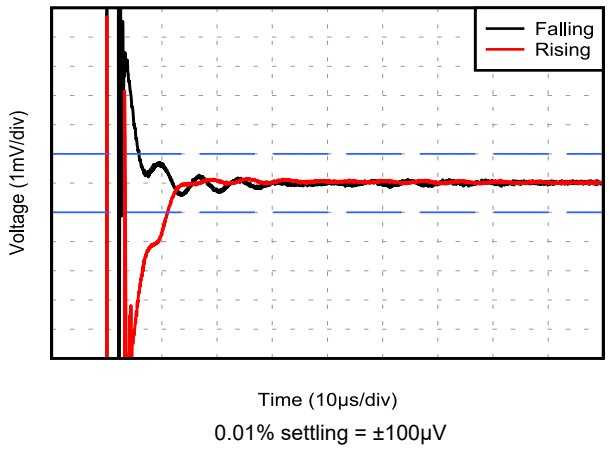


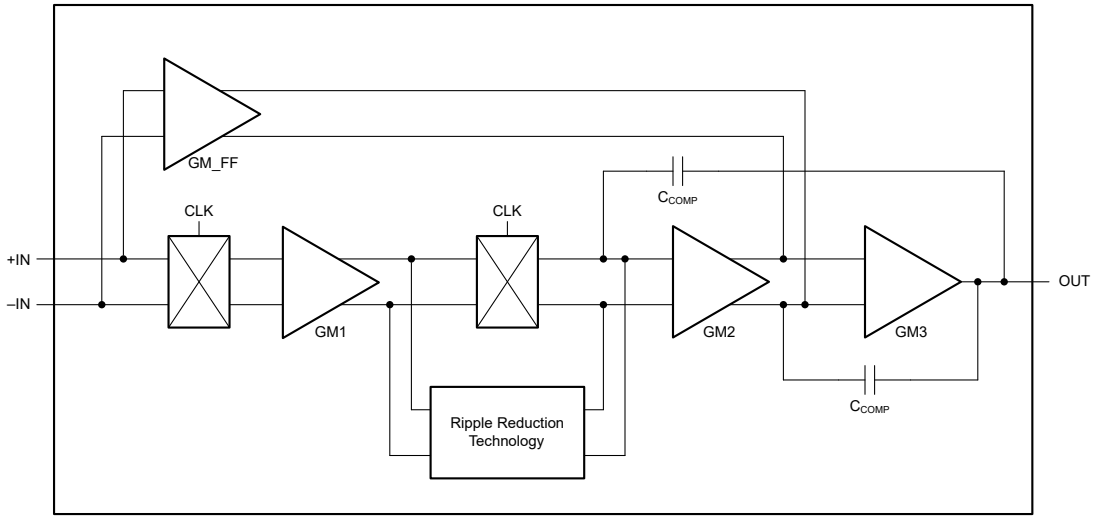
Figure 5-39. Settling Time

6 Detailed Description

6.1 Overview

The OPAx383 family of low-power zero-drift amplifiers is engineered with state-of-the-art, proprietary, precision zero-drift technology. These amplifiers offer ultra-low input offset voltage and drift, and achieve excellent input and output dynamic linearity. The OPAx383 operate from 1.7V to 5.5V, are unity-gain stable, and are designed for a wide range of general-purpose and precision applications. The OPAx383 strengths also include a 2.5MHz bandwidth, 32nV/$\sqrt{\text{Hz}}$ noise spectral density for typical 65uA of quiescent current per amplifier, and no 1/f noise. These features make the OPAx383 an excellent choice for interfacing with sensor modules, and buffering high-fidelity, digital-to-analog converters (DACs), and analog-to-digital convertors (ADCs).

6.2 Functional Block Diagram



Copyright © 2026 Texas Instruments Incorporated

6.3 Feature Description

6.3.1 Input Bias Current

During normal operation, the typical input bias current of the OPAx383 is 10pA. The device exhibits low drift over the full temperature range of –40°C to +125°C. There are no antiparallel diodes between the input pins (+IN and –IN); therefore, the differential input maximum voltage is limited only by diodes connected to the supply voltage pins. However, use caution in cases where the input differential voltage exceeds the nominal operating input differential voltage. When inputs are separated, the switching offset-cancellation path internal to the amplifier exceeds normal operating conditions, and can potentially create long settling behavior upon return to normal operation. Figure 6-1 shows the equivalent input circuit of OPAx383.

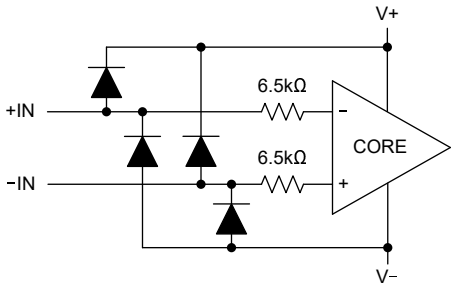


Figure 6-1. Equivalent Input Circuit

6.3.2 EMI Susceptibility and Input Filtering

Operational amplifiers can exhibit sensitivity to electromagnetic interference (EMI). Typically, conducted EMI (that is, EMI that enters the device through conduction) is more commonly observed than radiated EMI (that is, EMI that enters the device through radiation). When conducted EMI enters the operational amplifier, the dc offset at the amplifier output can shift from the nominal value. This shift is a result of signal rectification associated with the internal semiconductor junctions. Although all operational amplifier pin functions can be affected by EMI, the input pins are likely to be the most susceptible. The OPAx383 operational amplifier family incorporates an internal input low-pass filter that reduces the amplifier response to EMI. Both common-mode and differential-mode filtering are provided by the input filter. The conducted EMI rejection of the OPAx383 is seen in Figure 6-2.

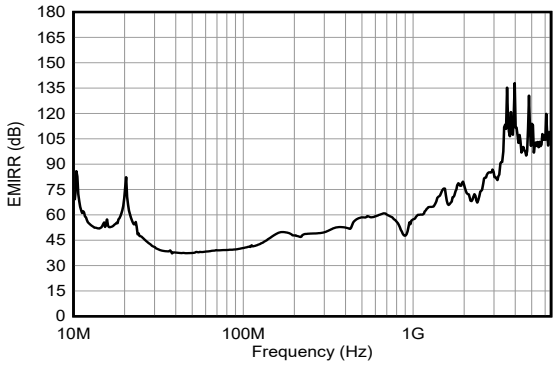


Figure 6-2. EMI Rejection Ratio

6.4 Device Functional Modes

The OPAx383 have a single functional mode and are operational when the power-supply voltage is greater than 1.7V (±0.85V). The maximum specified power-supply voltage for the OPAx383 is 5.5V (±2.75V). The OPA383S features a shutdown pin, which can be used to place the op amp into a low-power mode.

Copyright © 2026 Texas Instruments Incorporated

7 Application and Implementation

Note

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

7.1 Application Information

The OPAx383 are unity-gain stable, precision, operational amplifiers featuring state-of-the-art, zero-drift technology. The use of proprietary zero-drift circuitry gives the benefit of low input offset voltage over time and temperature, as well as lower 1/f noise component. As a result of the high PSRR, the devices work well in applications that run directly from battery power without regulation. The OPAx383 family is optimized for full rail-to-rail input, allowing for low-voltage, single-supply operation or split-supply use. These miniature, high-precision, low-noise amplifiers offer high-impedance inputs that have a common-mode range 100mV beyond the supplies without input crossover distortion, and a rail-to-rail output that swings within 5mV of the supplies under normal test conditions. The OPAx383 precision amplifiers are designed for upstream analog signal-chain applications in low or high gains, as well as downstream signal-chain functions, such as DAC buffering.

7.1.1 Zero-Drift Clocking

The OPAx383 use an advanced zero-drift architecture to achieve ultra-low offset and offset drift. This architecture uses a clock and switches internally to create a dc error-correction path. The clocking is filtered internally, and typically not observable for most configurations. Take the following precautions to minimize clock noise in the signal chain. The clocking creates a small charge-injection pulse at the input of the amplifier; therefore, do not use high-value resistors (> 100kΩ) in series with the inputs to avoid higher clock voltage noise at the output. The charge injection pulses are minimized when the impedance to the input pins is matched. If higher value resistors are used, then use matching impedances on both amplifier input pins.

7.2 Typical Applications

7.2.1 Bidirectional Current Sensing

This single-supply, low-side, bidirectional current-sensing design example detects load currents from –1A to +1A. The single-ended output spans from 110mV to 3.19V. This design uses the OPAx383 because of the device low offset voltage and rail-to-rail input and output. One of the amplifiers is configured as a difference amplifier and the other amplifier provides the reference voltage. Figure 7-1 shows the design example schematic.

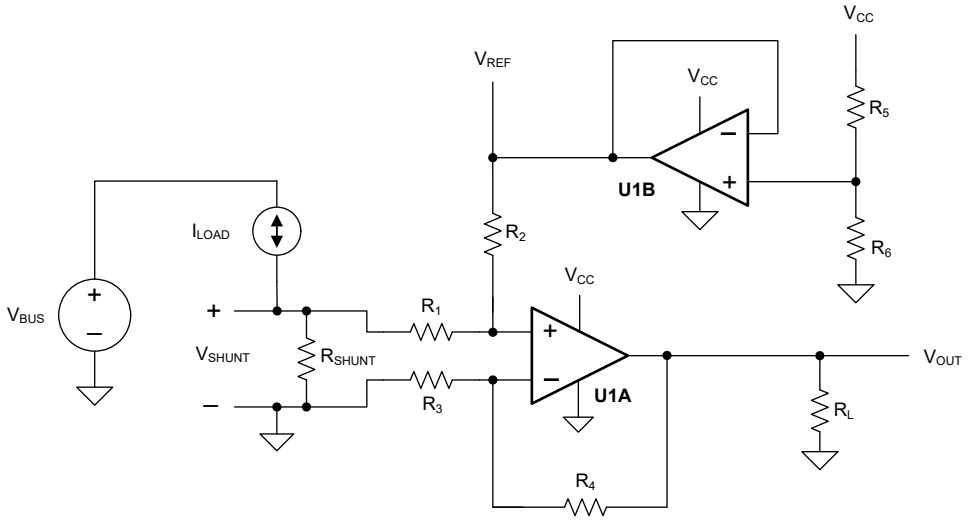


Figure 7-1. Bidirectional Current-Sensing Schematic

Copyright © 2026 Texas Instruments Incorporated

7.2.1.1 Design Requirements

This design has the following requirements:

- Supply voltage: 3.3V
- Input: –1A to +1A
- Output: 1.65V ±1.54V (110mV to 3.19V)

7.2.1.2 Detailed Design Procedure

The load current, I_{LOAD}, flows through the shunt resistor, R_{SHUNT}, to develop the shunt voltage, V_{SHUNT}. The shunt voltage is then amplified by the difference amplifier consisting of U1A and R_1 through R_4. The gain of the difference amplifier is set by the ratio of R_4 to R_3. To minimize errors, set $R_2 = R_4$ and $R_1 = R_3$. The reference voltage, V_{REF}, is supplied by buffering a resistor divider using U1B. The transfer function is given by Equation 1:

$$V_{OUT} = V_{SHUNT} \times Gain_{Diff\text{-}Amp} + V_{REF} \quad (1)$$

where

- $V_{SHUNT} = I_{LOAD} \times R_{SHUNT}$
- $Gain_{Diff\text{-}Amp} = \frac{R_4}{R_3}$
- $V_{REF} = V_{CC} \times \left(\frac{R_6}{R_5 + R_6}\right)$

There are two types of errors in this design: gain and offset. Gain errors are introduced by the tolerance of the shunt resistor and the ratios of R_4 to R_3 and, similarly, R_2 to R_1. Offset errors are introduced by the voltage divider (R_5 and R_6) and how closely the ratio of R_4 / R_3 matches R_2 / R_1. The latter value affects the CMRR of the difference amplifier, ultimately translating to an offset error.

The value of V_{SHUNT} is the ground potential for the system load because V_{SHUNT} is a low-side measurement. Therefore, a maximum value must be placed on V_{SHUNT}. In this design, the maximum value for V_{SHUNT} is set to 100mV. Equation 2 calculates the maximum value of the shunt resistor given a maximum shunt voltage of 100mV and maximum load current of 1A.

$$R_{SHUNT(MAX)} = \frac{V_{SHUNT(MAX)}}{I_{LOAD(MAX)}} = \frac{100mV}{1A} = 100m\Omega \quad (2)$$

The tolerance of R_{SHUNT} is directly proportional to cost. For this design, a shunt resistor with a tolerance of 0.5% is selected. If greater accuracy is required, select a 0.1% resistor or better.

The load current is bidirectional; therefore, the shunt voltage range is –100mV to +100mV. This voltage is divided down by R_1 and R_2 before reaching the operational amplifier, U1A. Make sure that the voltage present at the noninverting node of U1A is within the common-mode range of the device. Use an operational amplifier, such as the OPAx383, that has a common-mode range that extends below the negative supply voltage. The offset error is minimal because the OPAx383 has a typical offset voltage of merely ±0.5µV (±5µV, maximum).

Given a symmetric load current of –1A to +1A, the voltage divider resistors, R_5 and R_6, must be equal. To be consistent with the shunt resistor, a tolerance of 0.5% is selected. To minimize power consumption, 10kΩ resistors are used.

To set the gain of the difference amplifier, the common-mode range and output swing of the OPAx383 must be considered.Equation 3 and Equation 4 depict the typical common-mode range and maximum output swing, respectively, of the OPAx383 given a 3.3V supply.

$$-100mV < V_{CM} < 3.4V \quad (3)$$

$$100mV < V_{OUT} < 3.2V \quad (4)$$

The gain of the difference amplifier is now calculated using Equation 5.

Copyright © 2026 Texas Instruments Incorporated

$$\text{Gain}_{\text{Diff-Amp}} = \frac{V_{OUT(MAX)} - V_{OUT(MIN)}}{R_{SHUNT} \times (I_{MAX} - I_{MIN})} = \frac{3.2\text{V} - 100\text{mV}}{100\text{m}\Omega \times (1\text{A} - (-1\text{A}))} = 15.5\frac{\text{V}}{\text{V}} \quad (5)$$

The resistor value selected for R_1 and R_3 is 1kΩ. 15.4kΩ is selected for R_2 and R_4 because this number is the nearest standard value. Therefore, the calculated gain of the difference amplifier is 15.4V/V.

The gain error of the circuit primarily depends on R_1 through R_4. As a result of this dependence, select 0.1% resistors. This configuration reduces the likelihood that the design requires a two-point calibration. A simple one-point calibration, if desired, removes the offset errors introduced by the 0.5% resistors.

7.2.1.3 Application Curve

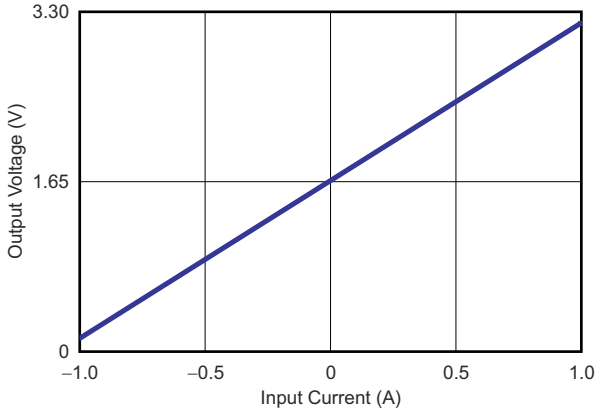


Figure 7-2. Bidirectional Current-Sensing Circuit Performance: Output Voltage vs Input Current

7.2.2 Bridge Sensor Measurement

Figure 7-3 shows the OPAx383 in a high-CMRR dual-op-amp instrumentation amplifier with a trim resistor and six-wire bridge sensor for ratio metric precision measurement.

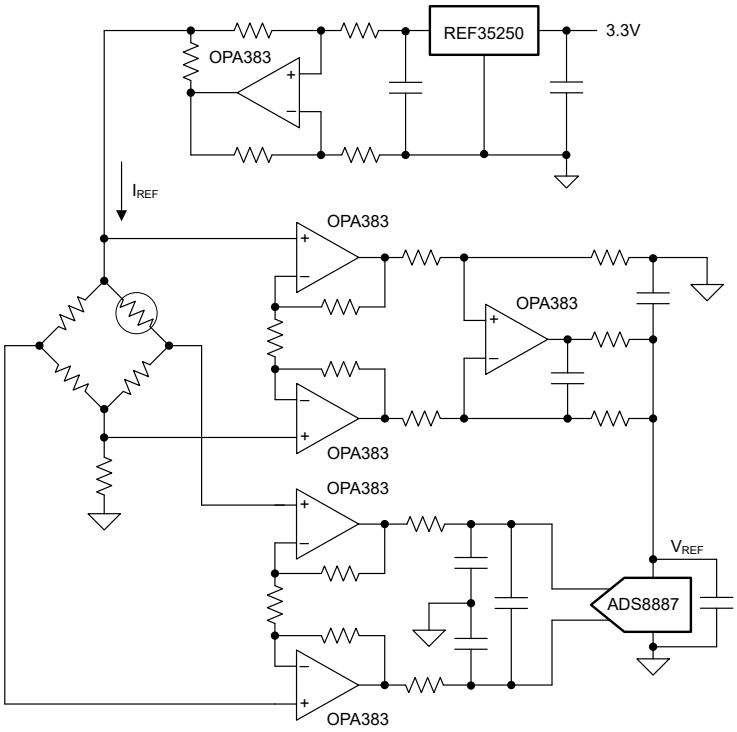


Figure 7-3. Bridge-Sensor Measurement Schematic

Copyright © 2026 Texas Instruments Incorporated

7.3 Power Supply Recommendations

The OPAx383 family of devices is specified for operation from 1.7V to 5.5V for single supplies, and ±0.85V to ±2.75V for dual supplies. Key parameters that can exhibit significant variance with regard to operating voltage are presented in Section 5.

CAUTION
Supply voltages greater than 6V can permanently damage the device (see Section 5.1).

7.4 Layout

7.4.1 Layout Guidelines

Pay attention to good layout practice. Keep traces short and, when possible, use a printed-circuit board (PCB) ground plane with surface-mount components placed as close to the device pins as possible. Place a 0.1µF capacitor close to the supply pins. These guidelines must be applied throughout the analog circuit to improve performance, and provide benefits such as reducing the electromagnetic interference (EMI) susceptibility.

For lowest offset voltage and precision performance, optimize circuit layout and mechanical conditions. Avoid temperature gradients that create thermoelectric (Seebeck) effects in the thermocouple junctions formed from connecting dissimilar conductors. Cancel these thermally-generated potentials by making sure that the potentials are equal on both input pins. Other layout and design considerations include:

- Use low thermoelectric-coefficient conditions (avoid dissimilar metals).
- Thermally isolate components from power supplies or other heat sources.
- Shield operational amplifier and input circuitry from air currents, such as cooling fans.

Follow these guidelines to reduce the likelihood of junctions being at different temperatures, which can cause thermoelectric voltage drift of 0.1µV/°C or greater depending on materials used.

7.4.2 Layout Example

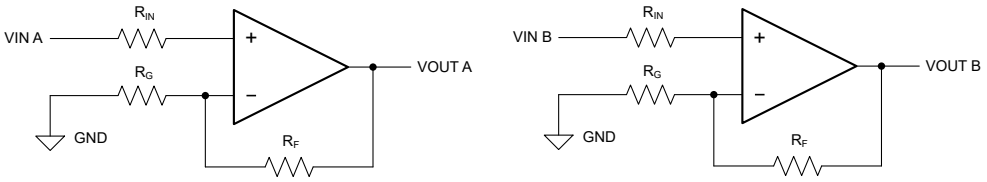


Figure 7-4. Schematic Representation

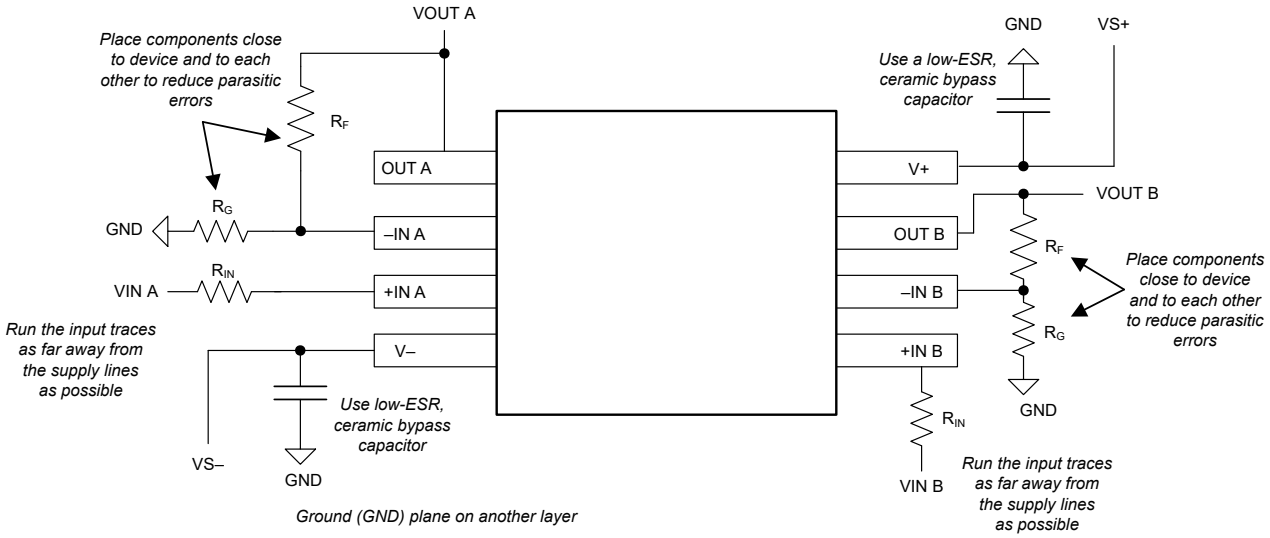


Figure 7-5. Layout Example

8 Device and Documentation Support

8.1 Device Support

8.1.1 Development Support

8.1.1.1 PSpice® for TI

PSpice® for TI is a design and simulation environment that helps evaluate performance of analog circuits. Create subsystem designs and prototype designs before committing to layout and fabrication, reducing development cost and time to market.

8.1.1.2 TINA-TI™ Simulation Software (Free Download)

TINA-TI™ simulation software is a simple, powerful, and easy-to-use circuit simulation program based on a SPICE engine. TINA-TI simulation software is a free, fully-functional version of the TINA™ software, preloaded with a library of macromodels, in addition to a range of both passive and active models. TINA-TI simulation software provides all the conventional dc, transient, and frequency domain analysis of SPICE, as well as additional design capabilities.

Available as a free download from the Design and simulation tools web page, TINA-TI simulation software offers extensive post-processing capability that allows users to format results in a variety of ways. Virtual instruments offer the ability to select input waveforms and probe circuit nodes, voltages, and waveforms, creating a dynamic quick-start tool.

Note

These files require that either the TINA software or TINA-TI software be installed. Download the free TINA-TI simulation software from the TINA-TI™ software folder.

8.2 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. Click on *Notifications* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

8.3 Support Resources

TI E2E™ support forums are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

Linked content is provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

8.4 Trademarks

TINA-TI™ and TI E2E™ are trademarks of Texas Instruments.
TINA™ is a trademark of DesignSoft, Inc.
PSpice® is a registered trademark of Cadence Design Systems, Inc.
All trademarks are the property of their respective owners.

8.5 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

8.6 Glossary

TI Glossary	This glossary lists and explains terms, acronyms, and definitions.

Copyright © 2026 Texas Instruments Incorporated

9 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Changes from Revision C (November 2025) to Revision D (April 2026)	Page
• Adding OPA383, Shutdown YCH package to *production*	1
• Added shutdown specifications to *Electrical Characteristics table*	6

Changes from Revision B (June 2025) to Revision C (November 2025)	Page
• Updated the status of OPA4383PWR from *preview* to *production*	1

Changes from Revision A (May 2025) to Revision B (June 2025)	Page
• Updated the status of OPA383DBVR from *preview* to *production*	1
• Added the following footnote to the room temperature maximum for input offset voltage: "Specification established from device population bench system measurements across multiple lots."	8
• Added the following footnote to the room temperature maximum for input bias current: "Specification established from device population bench system measurements across multiple lots."	8
• Changed the room temperature maximum input bias current from 50pA to 62pA	8
• Changed the -40°C to +85°C maximum input bias current from 60pA to 76pA	8
• Changed the -40°C to +125°C maximum input bias current from 150pA to 212pA	8
• Added the following footnote to the room temperature maximum for input offset current: "Specification established from device population bench system measurements across multiple lots."	8
• Changed the room temperature maximum input offset current from 100pA to 123pA	8
• Changed the room temperature minimum CMRR when V_S = 5.5V from 125dB to 122dB	8
• Changed the -40°C to +125°C minimum CMRR when V_S = 5.5V from 122dB to 120dB	8
• Added the following footnote to the room temperature minimum for CMRR where Vs = 1.7V: "Specification established from device population bench system measurements across multiple lots."	8
• Changed the room temperature minimum CMRR when V_S = 1.7V from 122dB to 116dB	8
• Changed the -40°C to +125°C minimum CMRR when V_S = 1.7V from 120dB to 114dB	8
• Changed the room temperature minimum A_{OL} when V_S = 5.5V and R_L = 10kΩ from 130dB to 120dB	8
• Added a room temperature minimum A_{OL} for V_S = 1.7V and R_L = 10kΩ	8
• Changed the -40°C to +125°C minimum A_{OL} when V_S = 5.5V and R_L = 10kΩ from 124dB to 119dB	8
• Changed the room temperature minimum A_{OL} when V_S = 5.5V and R_L = 2kΩ from 125dB to 119dB	8
• Added a room temperature minimum A_{OL} for V_S = 1.7V and R_L = 2kΩ	8
• Changed the -40°C to +125°C minimum A_{OL} when V_S = 5.5V and R_L = 2kΩ from 122dB to 118dB	8
• Changed overload recovery time from 1500ns to 2200ns	8

Changes from Revision * (December 2024) to Revision A (May 2025)	Page
• Update to APL the OPA383 and OPA4383	1

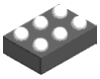
10 Mechanical, Packaging, and Orderable Information

The following pages include mechanical packaging and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

Copyright © 2026 Texas Instruments Incorporated

OPA383YCHx

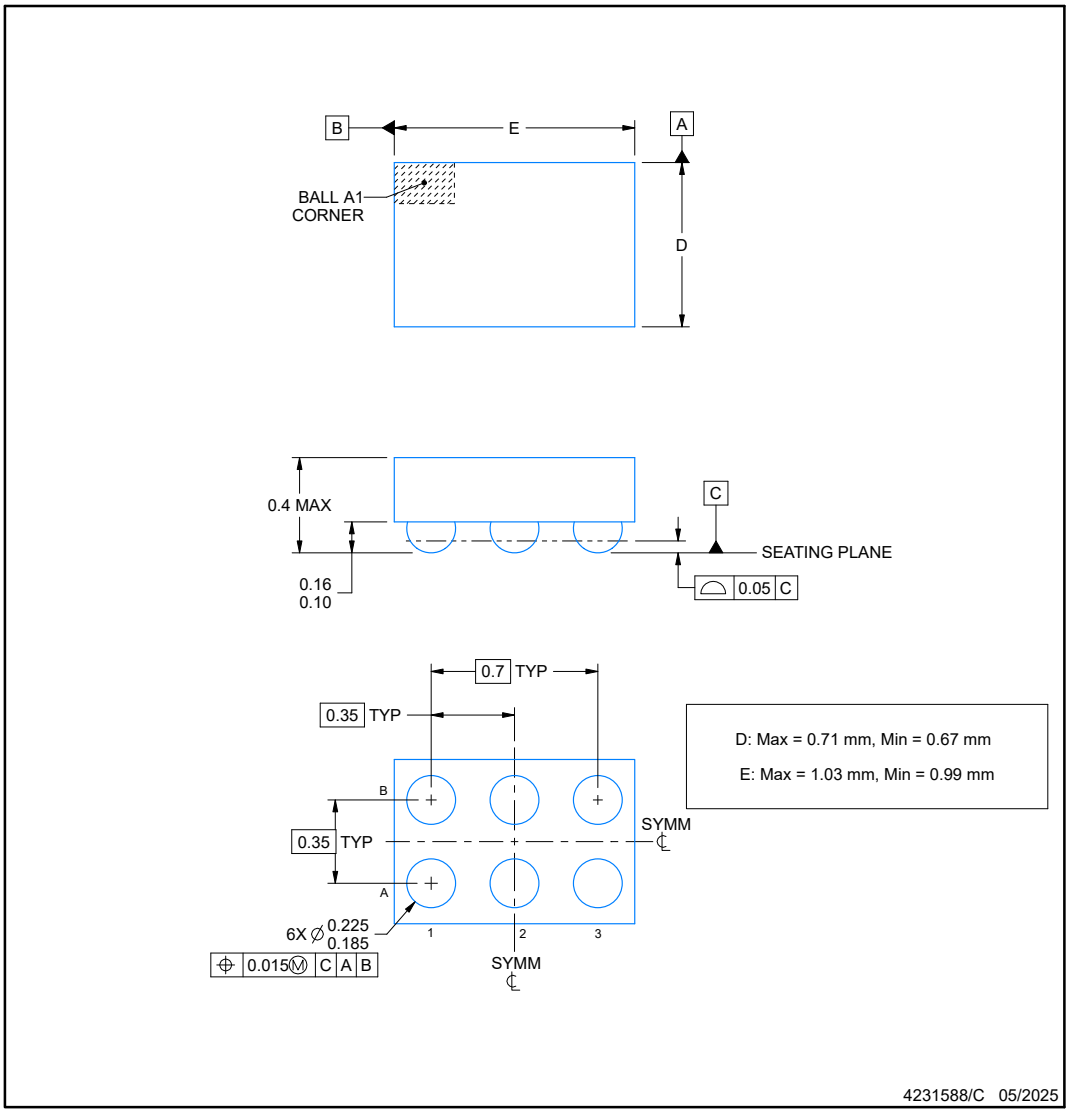
YCH0006-C01



PACKAGE OUTLINE

DSBGA - 0.4 mm max height

DIE SIZE BALL GRID ARRAY



NOTES:

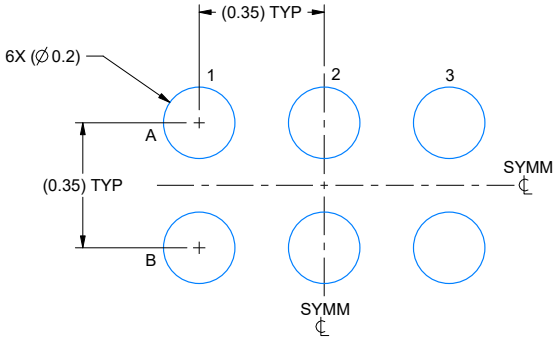
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.

Copyright © 2026 Texas Instruments Incorporated

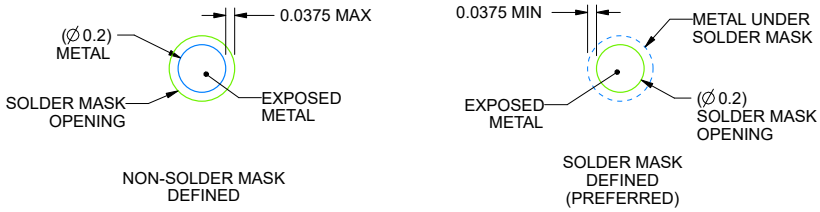
EXAMPLE BOARD LAYOUT

YCH0006-C01 — **DSBGA - 0.4 mm max height**

DIE SIZE BALL GRID ARRAY



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE: 60X



SOLDER MASK DETAILS
NOT TO SCALE

4231588/C 05/2025

NOTES: (continued)

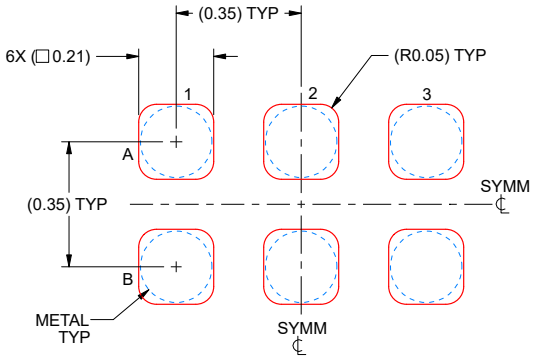
3. Final dimensions may vary due to manufacturing tolerance considerations and also routing constraints. See Texas Instruments Literature No. SNVA009 (www.ti.com/lit/snva009).

Copyright © 2026 Texas Instruments Incorporated

EXAMPLE STENCIL DESIGN

YCH0006-C01 **DSBGA - 0.4 mm max height**

DIE SIZE BALL GRID ARRAY



SOLDER PASTE EXAMPLE
BASED ON 0.075 mm THICK STENCIL
SCALE: 60X

4231588/C 05/2025

NOTES: (continued)

4. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release.

Copyright © 2026 Texas Instruments Incorporated

PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package | Pins	Package qty | Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
OPA2383DGKR	Active	Production	VSSOP (DGK) | 8	2500 | LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	O2383
OPA2383DGKR.A	Active	Production	VSSOP (DGK) | 8	2500 | LARGE T&R	Yes	SN	Level-1-260C-UNLIM	See OPA2383DGKR	O2383
OPA383DBVR	Active	Production	SOT-23 (DBV) | 5	3000 | LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	3PMF
OPA383YCHR	Active	Production	DSBGA (YCH) | 6	3000 | LARGE T&R	Yes	SNAGCU	Level-1-260C-UNLIM	-40 to 125	X
OPA4383PWR	Active	Production	TSSOP (PW) | 14	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	O4383PW

(1) **Status:** For more details on status, see our product life cycle.

(2) **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

(3) **RoHS values:** Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

(4) **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

(5) **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

(6) **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

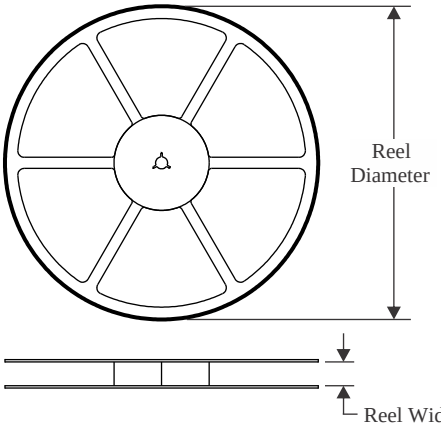
Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

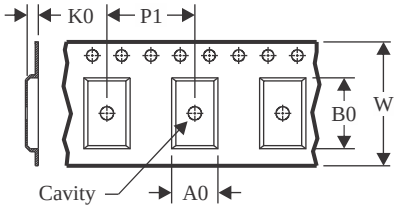
In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

TAPE AND REEL INFORMATION

REEL DIMENSIONS

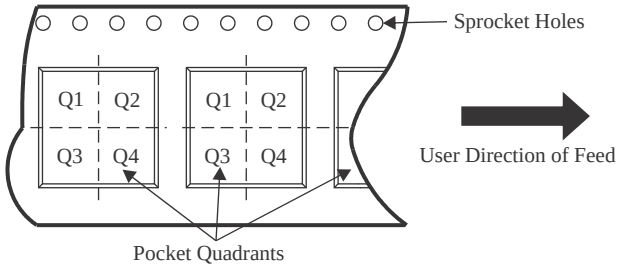


TAPE DIMENSIONS



A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

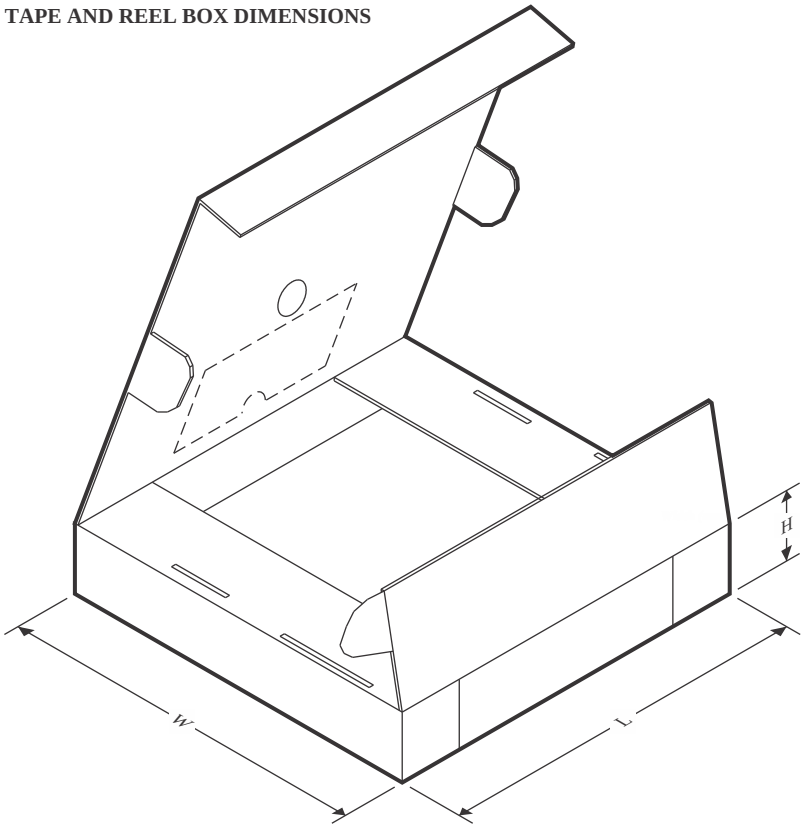
QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
OPA2383DGKR	VSSOP	DGK	8	2500	330.0	12.4	5.25	3.35	1.25	8.0	12.0	Q1
OPA383DBVR	SOT-23	DBV	5	3000	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
OPA383YCHR	DSBGA	YCH	6	3000	180.0	8.4	0.74	1.06	0.53	2.0	8.0	Q2
OPA4383PWR	TSSOP	PW	14	3000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1

TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

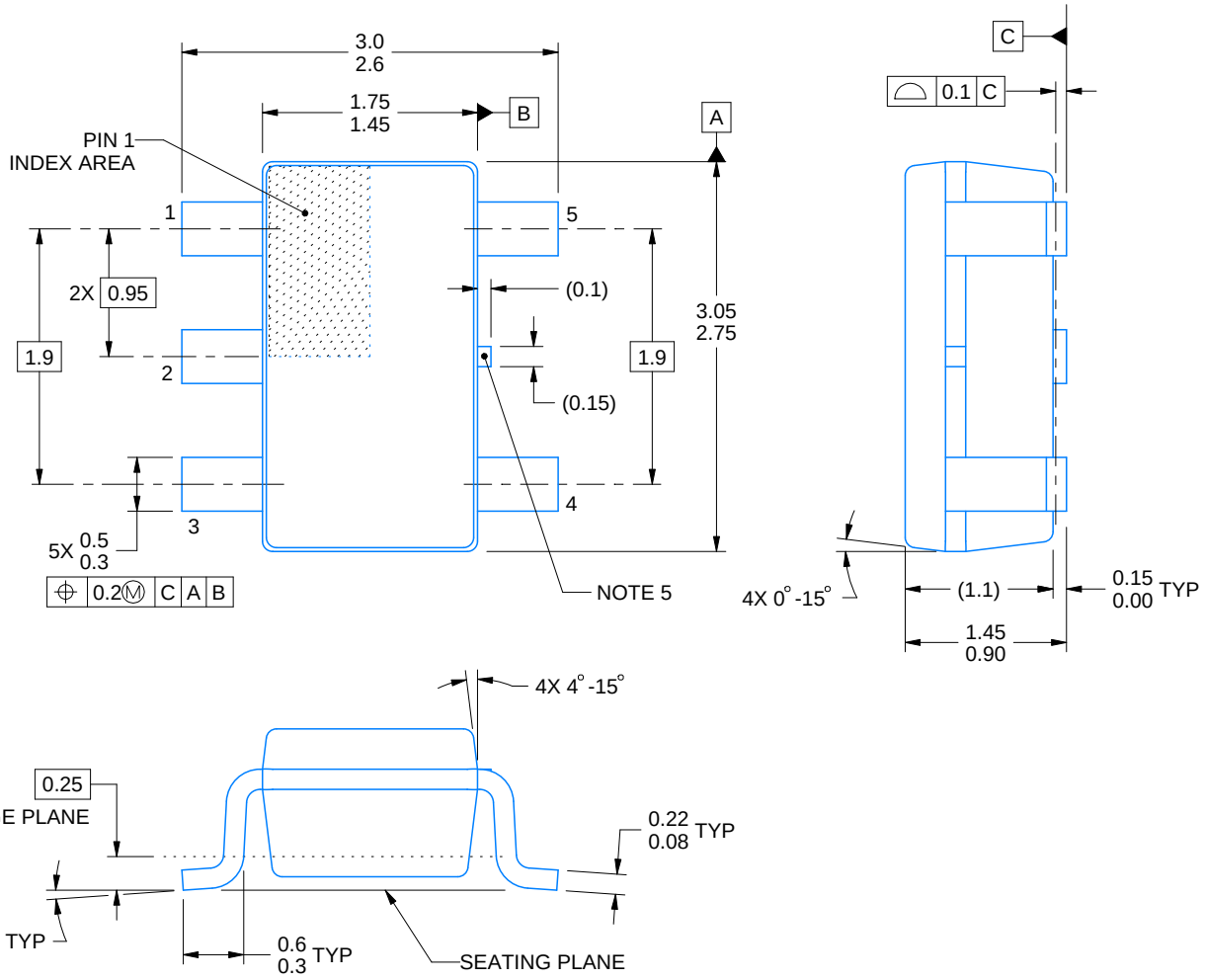
Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
OPA2383DGKR	VSSOP	DGK	8	2500	366.0	364.0	50.0
OPA383DBVR	SOT-23	DBV	5	3000	210.0	185.0	35.0
OPA383YCHR	DSBGA	YCH	6	3000	182.0	182.0	20.0
OPA4383PWR	TSSOP	PW	14	3000	353.0	353.0	32.0

PACKAGE OUTLINE

DBV0005A

SOT-23 - 1.45 mm max height

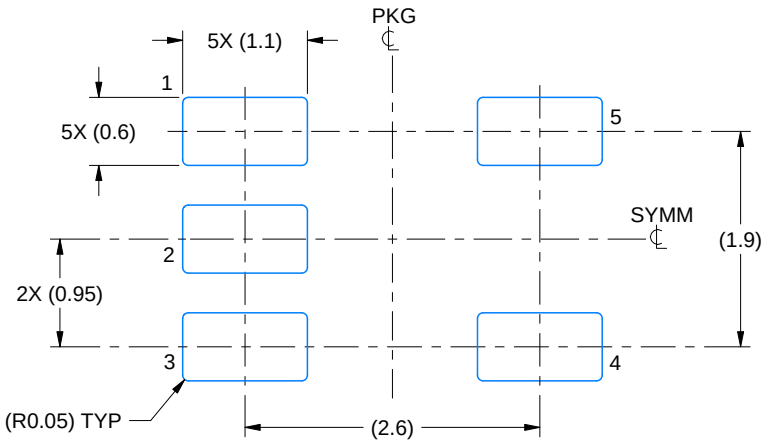
SMALL OUTLINE TRANSISTOR



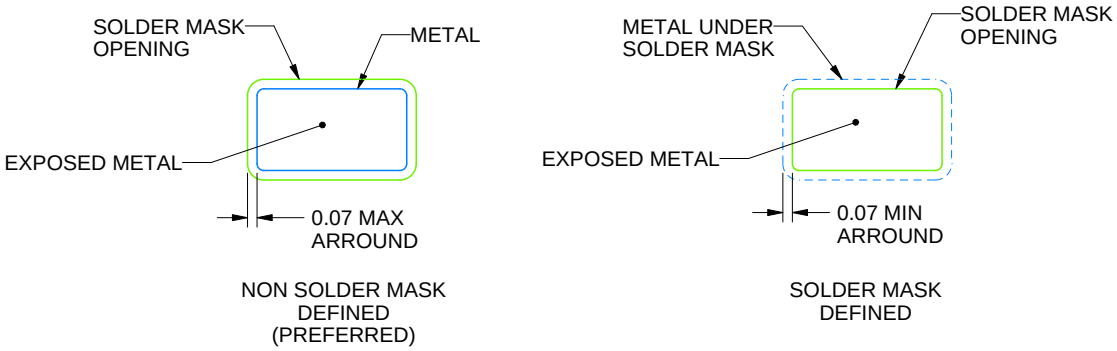
4214839/K 08/2024

NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. Refernce JEDEC MO-178.
4. Body dimensions do not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.25 mm per side.
5. Support pin may differ or may not be present.



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE:15X

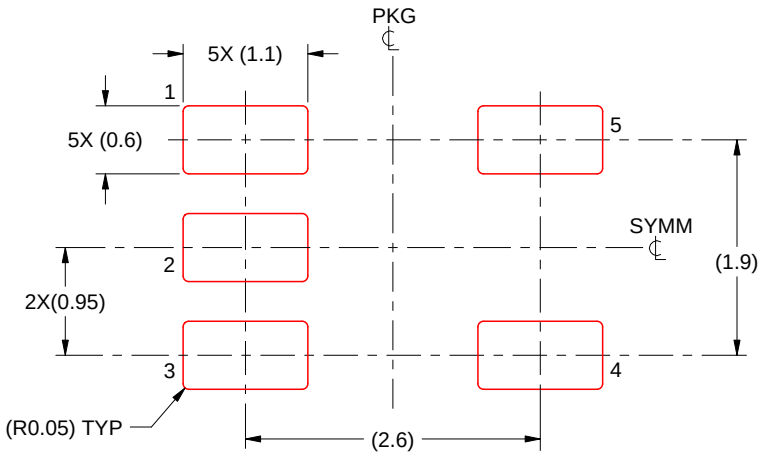


SOLDER MASK DETAILS

4214839/K 08/2024

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE:15X

4214839/K 08/2024

NOTES: (continued)

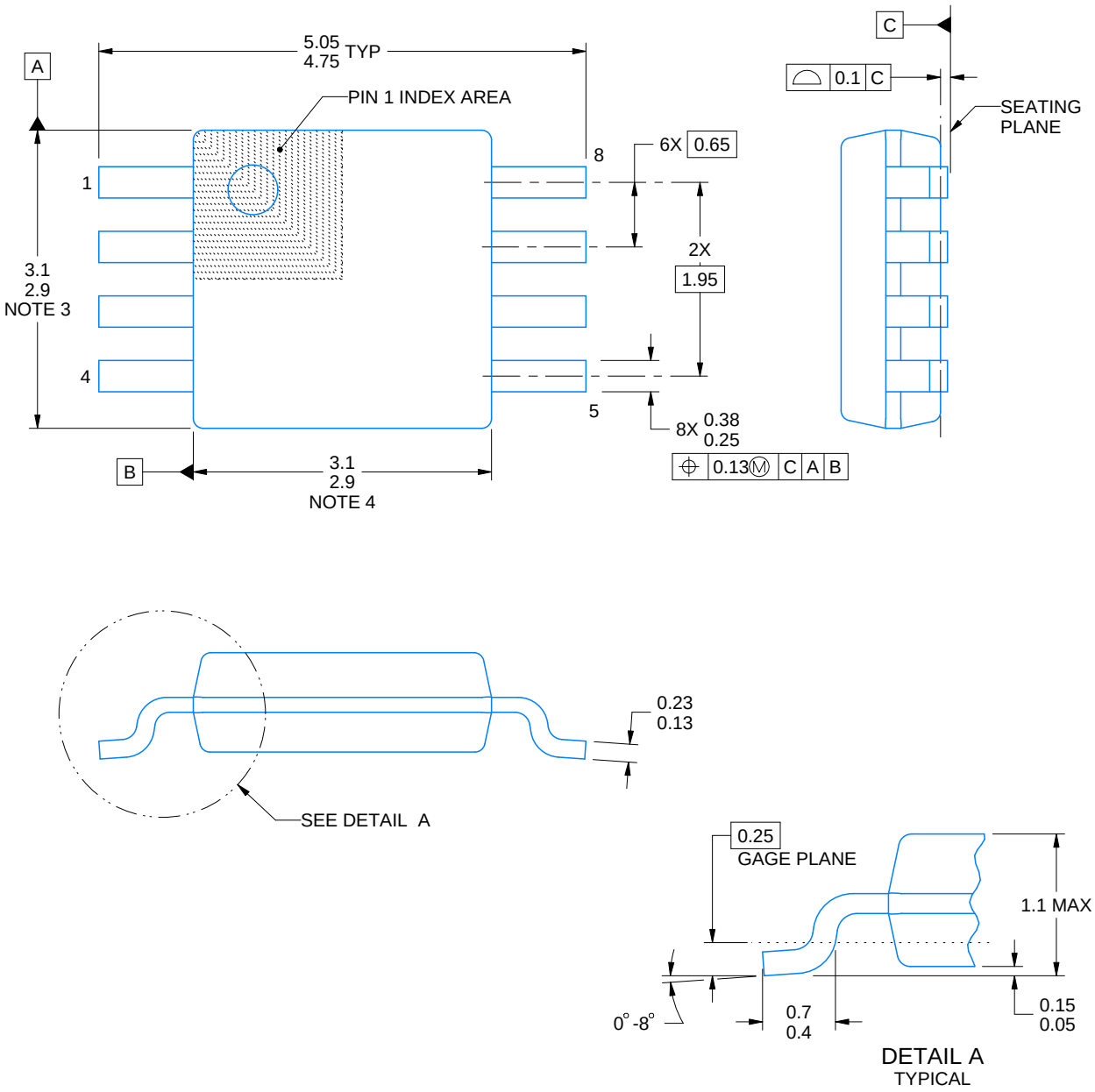
8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

PACKAGE OUTLINE

DGK0008A

VSSOP - 1.1 mm max height

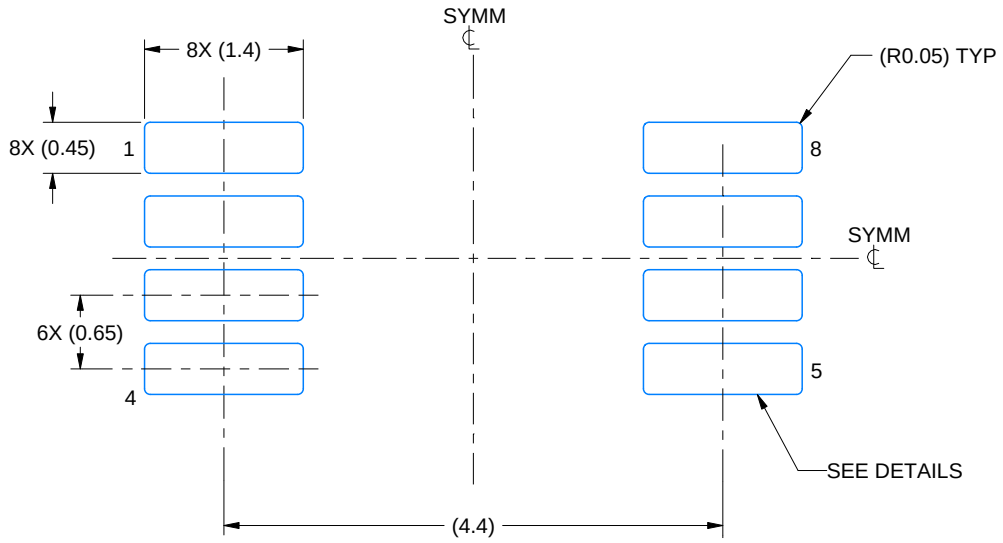
SMALL OUTLINE PACKAGE



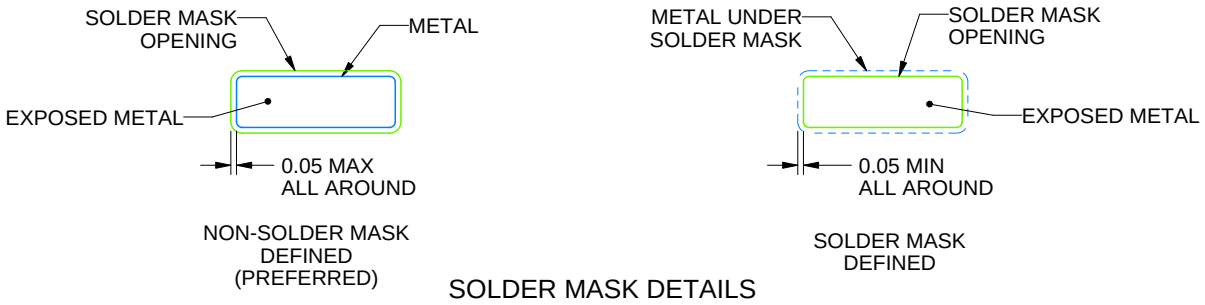
PowerPAD is a trademark of Texas Instruments.

NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
5. Reference JEDEC registration MO-187.



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE: 15X

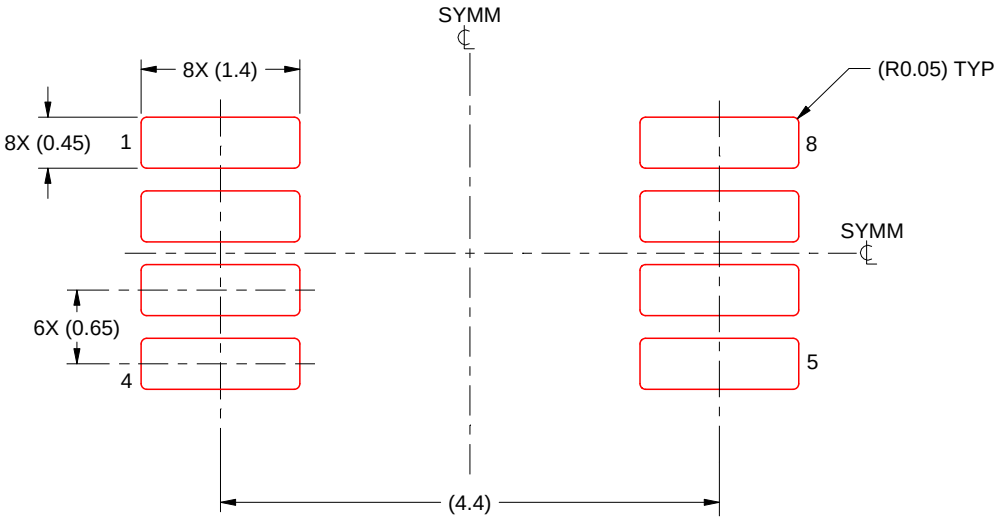


SOLDER MASK DETAILS

4214862/A 04/2023

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.
8. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.
9. Size of metal pad may vary due to creepage requirement.



SOLDER PASTE EXAMPLE
SCALE: 15X

4214862/A 04/2023

NOTES: (continued)

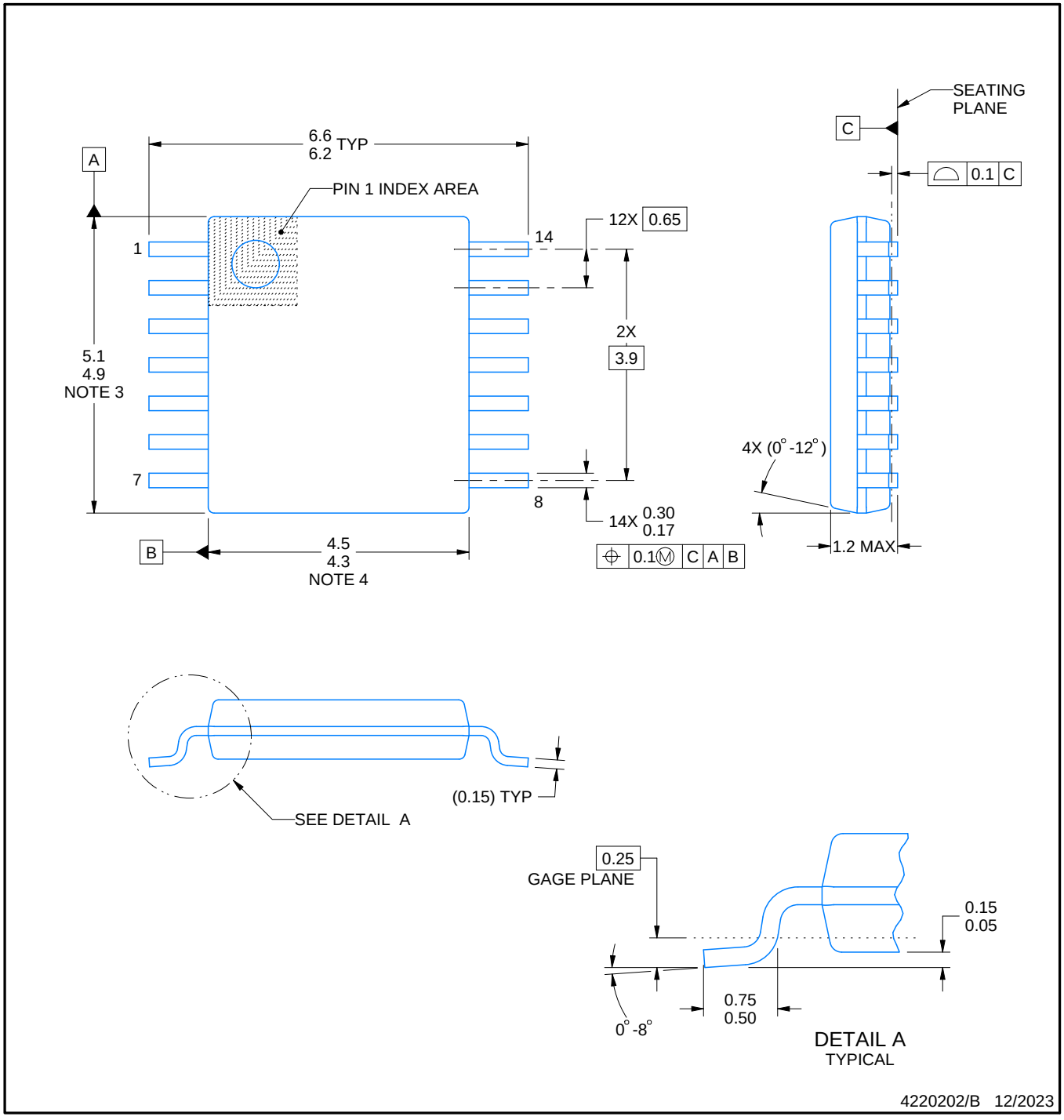
11. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
12. Board assembly site may have different recommendations for stencil design.

PACKAGE OUTLINE

PW0014A

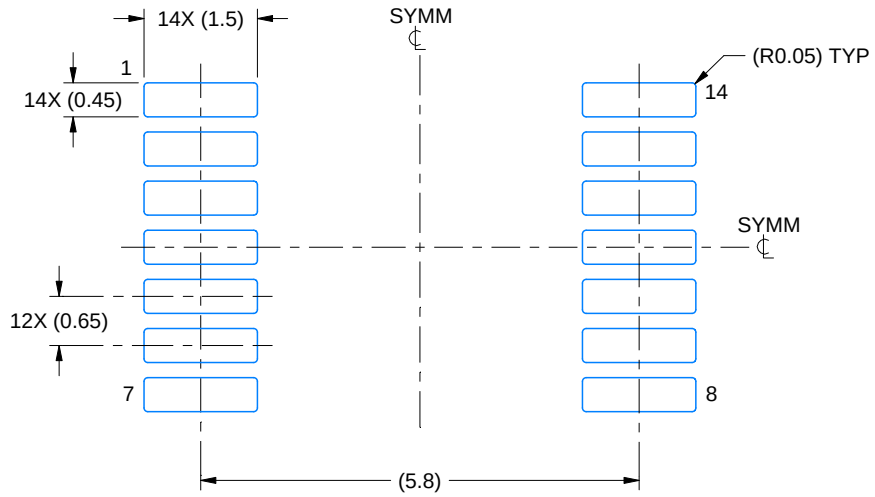
TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE

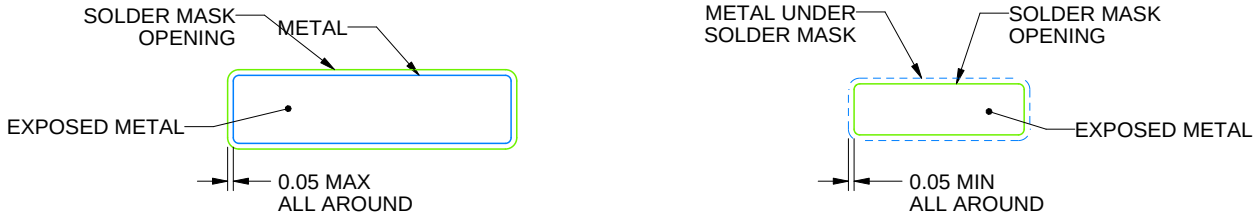


NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
5. Reference JEDEC registration MO-153.



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE: 10X

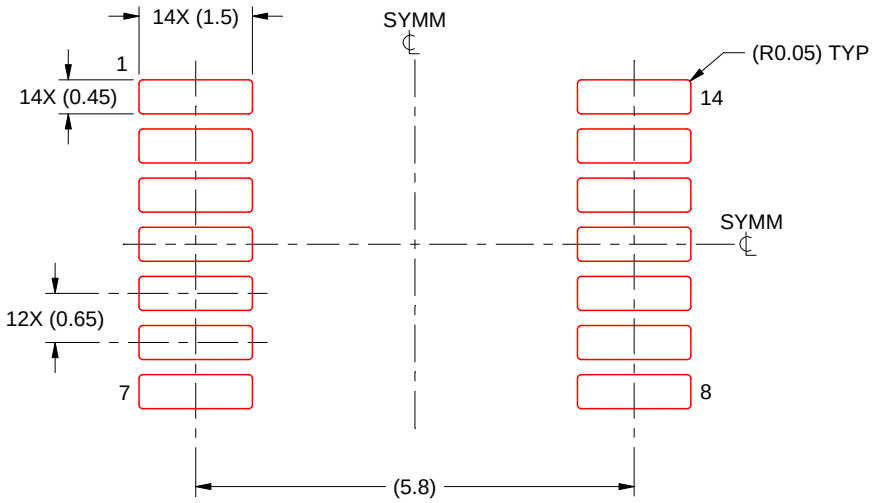


SOLDER MASK DETAILS

4220202/B 12/2023

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE: 10X

4220202/B 12/2023

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

IMPORTANT NOTICE AND DISCLAIMER

TI PROVIDES TECHNICAL AND RELIABILITY DATA (INCLUDING DATASHEETS), DESIGN RESOURCES (INCLUDING REFERENCE DESIGNS), APPLICATION OR OTHER DESIGN ADVICE, WEB TOOLS, SAFETY INFORMATION, AND OTHER RESOURCES “AS IS” AND WITH ALL FAULTS, AND DISCLAIMS ALL WARRANTIES, EXPRESS AND IMPLIED, INCLUDING WITHOUT LIMITATION ANY IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE OR NON-INFRINGEMENT OF THIRD PARTY INTELLECTUAL PROPERTY RIGHTS.

These resources are intended for skilled developers designing with TI products. You are solely responsible for (1) selecting the appropriate TI products for your application, (2) designing, validating and testing your application, and (3) ensuring your application meets applicable standards, and any other safety, security, regulatory or other requirements.

These resources are subject to change without notice. TI grants you permission to use these resources only for development of an application that uses the TI products described in the resource. Other reproduction and display of these resources is prohibited. No license is granted to any other TI intellectual property right or to any third party intellectual property right. TI disclaims responsibility for, and you fully indemnify TI and its representatives against any claims, damages, costs, losses, and liabilities arising out of your use of these resources.

TI’s products are provided subject to TI’s Terms of Sale, TI’s General Quality Guidelines, or other applicable terms available either on ti.com or provided in conjunction with such TI products. TI’s provision of these resources does not expand or otherwise alter TI’s applicable warranties or warranty disclaimers for TI products. Unless TI explicitly designates a product as custom or customer-specified, TI products are standard, catalog, general purpose devices.

TI objects to and rejects any additional or different terms you may propose.

Copyright © 2026, Texas Instruments Incorporated

Last updated 10/2025